

TLE5012
TLE5012-E0318
TLE5012-E0742
GMR-Based Angular Sensor
for Rotor Position Sensing

Target
Data Sheet
V 0.41

Sensors



Never stop thinking

Edition 2009-02

**Published by
Infineon Technologies AG
81726 München, Germany**

**© 2008 Infineon Technologies AG
All Rights Reserved.**

Legal Disclaimer

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party.

Information

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (www.infineon.com).

Warnings

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

Infineon Technologies components may be used in life-support devices or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

1	Product Description	7
1.1	Overview	7
1.2	Features	8
1.3	Application Example	8
2	Functional Description	9
2.1	General	9
2.2	Pin Configuration	11
2.3	Pin Description	11
2.4	Block Diagram	12
2.5	Functional Block Description	12
2.5.1	Internal Power Supply	12
2.5.2	Oscillator and PLL	12
2.5.3	SD-ADC	12
2.5.4	Digital Signal Processing Unit	13
2.5.5	Interfaces	13
2.5.6	Safety Features	13
3	Specification	14
3.1	Application Circuit	14
3.2	Absolute Maximum Ratings	17
3.3	Operating Range	17
3.4	Characteristics	19
3.4.1	Electrical Parameters	19
3.4.2	ESD Protection	19
3.4.3	GMR Parameters	20
3.4.4	Angle Performance	21
3.4.5	Signal Processing	21
3.4.6	Clock Supply (CLK Timing Definition)	23
3.5	Interfaces	24
3.5.1	Synchronous Serial Communication (SSC) Interface	24
3.5.1.1	SSC Timing Definition	25
3.5.1.2	SSC Data Transfer	27
3.5.1.3	Registers Chapter	30
3.5.1.3.1	TLE5012 Register	31
3.5.2	Pulse Width Modulation Interface	46
3.5.3	Hall Switch Mode	48
3.5.4	Incremental Interface	50
3.6	Overvoltage Comparators	52
3.6.1	Internal Supply Voltage Comparators	52
3.6.2	V _{DD} Overvoltage Detection	52
3.6.3	GND - Off Comparator	52
3.6.4	V _{DD} - Off Comparator	53
4	Package Information	54
4.1	Package Parameters	54
4.2	Package Outline	54
4.3	Footprint	55
4.4	Packing	55
4.5	Marking	55

Figure 1	Sensitive Bridges of the GMR Sensor	9
Figure 2	Ideal Output of the GMR Sensor Bridges	10
Figure 3	Pin Configuration (Top View)	11
Figure 4	TLE5012 Block Diagram	12
Figure 5	PRO-SIL™ Logo	13
Figure 6	Application Circuit for TLE5012 with SSC and PWM Interface (using internal CLK)	14
Figure 7	Application Circuit for TLE5012 with HS Mode (using internal CLK)	15
Figure 8	Application Circuit for TLE5012 with SSC and IIF Interface (using external CLK)	15
Figure 9	Application Circuit for TLE5012 with only PWM Interface (using internal CLK)	16
Figure 10	Offset and Amplitude Definition	20
Figure 11	TLE5012 Signal path	21
Figure 12	Delay of Sensor Output	22
Figure 13	External CLK Timing Definition	23
Figure 14	SSC Configuration in Sensor-Slave Mode with Push-Pull Outputs (High Speed Application)	24
Figure 15	SSC Configuration in Sensor-Slave Mode and Open Drain (Safe Bus Systems)	25
Figure 16	SSC Timing	25
Figure 17	SSC Data Transfer (Data Read Example)	27
Figure 18	SSC Data Transfer (Data Write Example)	27
Figure 19	SSC Bit Ordering (Read Example)	29
Figure 20	Fast CRC Polynomial Division Circuit	29
Figure 21	Typical Example for a PWM Signal	47
Figure 22	Hall Switch Mode	48
Figure 23	HS Hysteresis	50
Figure 24	Incremental Interface Protocol	50
Figure 25	IIF Index Coding	51
Figure 26	OV Comparator	52
Figure 27	GND - Off Comparator	53
Figure 28	V _{DD} - Off Comparator	53
Figure 29	PG-DSO-8 Package Dimension	54
Figure 30	Footprint PG-DSO-8	55
Figure 31	Tape and Reel	55

Table 1	Pin Description	11
Table 2	Absolute Maximum Ratings	17
Table 3	Operating Range	17
Table 4	Electrical Parameters	19
Table 5	ESD Protection	19
Table 6	Basic GMR Parameters	20
Table 7	Angle Performance	21
Table 8	Signal Processing	22
Table 9	CLK Timing Specification	23
Table 10	PAD Characteristic	24
Table 11	SSC Push-Pull Timing Specification	25
Table 12	SSC Open Drain Timing Specification	26
Table 13	Structure of the Command Word	27
Table 14	Structure of the Safety Word	28
Table 15	Registers Overview	30
Table 16	PWM Interface	47
Table 17	Hall Switch Mode	48
Table 18	Incremental Interface	51
Table 19	Test Comparators	52
Table 20	Package Parameters	54

1 Product Description

1.1 Overview

The TLE5012 is a 360° angle sensor that detects the orientation of a magnetic field. This is achieved by measuring sine and cosine angle components with monolithic integrated **Giant Magneto Resistance (iGMR)** elements.

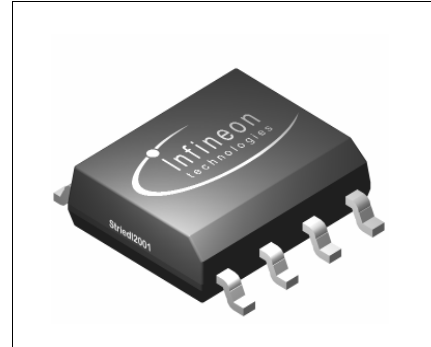
High precision angle values are achieved over temperature and lifetime using internal autocalibration algorithm.

Data communications are accomplished with a bi-directional SSC Interface that is SPI compatible.

The absolute angle value and other values are transmitted via SSC or via a Pulse-Width-Modulation (PWM) Protocol. Also the sine and cosine raw values can be read out. These raw signals are digitally processed internally to calculate the angle orientation of the magnetic field (magnet).

The TLE5012 is a precalibrated sensor. The calibration parameters are stored in laser fuses. At start-up the values of the fuses are written into Flip-Flops, where these values can be changed by the application specific parameters. The TLE5012-E0318 and TLE5012-E0742 are especially configured in a Hall-Switch emulation mode for motors with three or seven pole pairs.

Online diagnostic functions are provided to ensure reliable operation.



Product Type	Marking	Ordering Code	Package
TLE5012	5012	SP000477068	PG-DSO-8
TLE5012-E0318	5012E03	SP000611246	PG-DSO-8
TLE5012-E0742	5012E07	SP000611250	PG-DSO-8

1.2 Features

- **Giant Magneto Resistance (GMR)**-based principle
- Integrated magnetic field sensing for angle measurement
- Full calibrated 0 - 360° angle measurement with revolution counter and angle speed measurement
- Two separate highly accurate single bit SD-ADC
- 15 bit representation of absolute angle value on the output (resolution of 0.01°)
- 16 bit representation of sine / cosine values on the interface
- Max. 1.0° angle error over lifetime and temperature with activated auto-calibration
- Bi-directional SSC Interface up to 8Mbit/s
- Supports SIL3 with diagnostic functions and status information
- Interfaces: SSC, PWM, Incremental Interface (IIF), Hall Switch Mode (HSM)
- 0.25 µm CMOS technology
- Automotive qualified: -40°C to 150°C (Junction Temperature)
- ESD > 2kV (HBM)
- Green package with lead-free (Pb-free) plating

1.3 Application Example

The TLE5012 GMR-Based Angular Sensor is designed for angular position sensing in automotive applications, such as:

- Electrical Commutated Motor (e.g. used in **Electric Power Steering (EPS)**)
- Rotary Switch
- Steering Angle
- General Angular Sensing

2 Functional Description

2.1 General

The GMR sensor is implemented using vertical integration. This means that the GMR sensitive areas are integrated above the logic portion of the TLE5012 device. These GMR elements change their resistance depending on the direction of the magnetic field.

Four individual GMR elements are connected to one Wheatstone Sensor Bridge. These GMR elements sense one of two components of the applied magnetic field:

- X component, V_x (cosine) or the
- Y component, V_y (sine)

The advantage of a full-bridge structure is that the amplitude of the GMR signal is doubled and temperature effects cancel out each other.

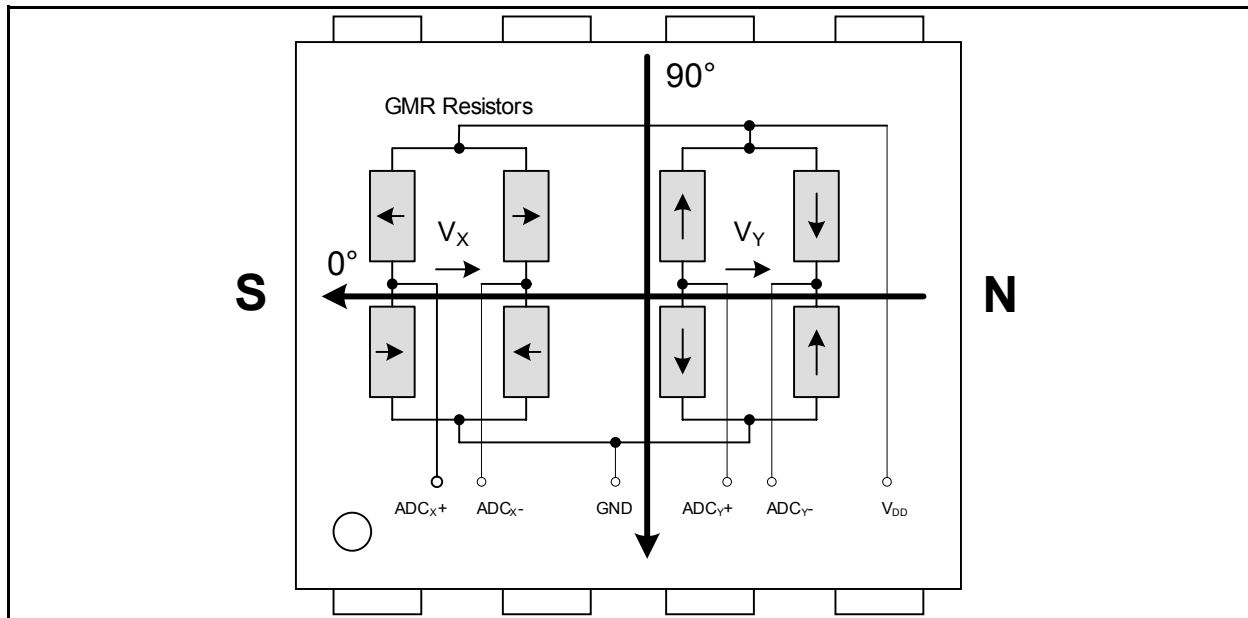


Figure 1 Sensitive Bridges of the GMR Sensor

Note: In Figure 1, the arrows in the resistors symbolize the direction of the Reference Layer, which is used for the further explanation.

The output signal of each bridge is only unambiguous over 180° between two maxima. Therefore two bridges are orientated orthogonally to each other to measure 360°.

With the trigonometric function ARCTAN, the true 360° angle value can be calculated which is represented by the relation of X and Y signals.

Because only the relative values influence the result, the absolute size of the two signals is of minor importance. Therefore, most influences to the amplitudes are compensated.

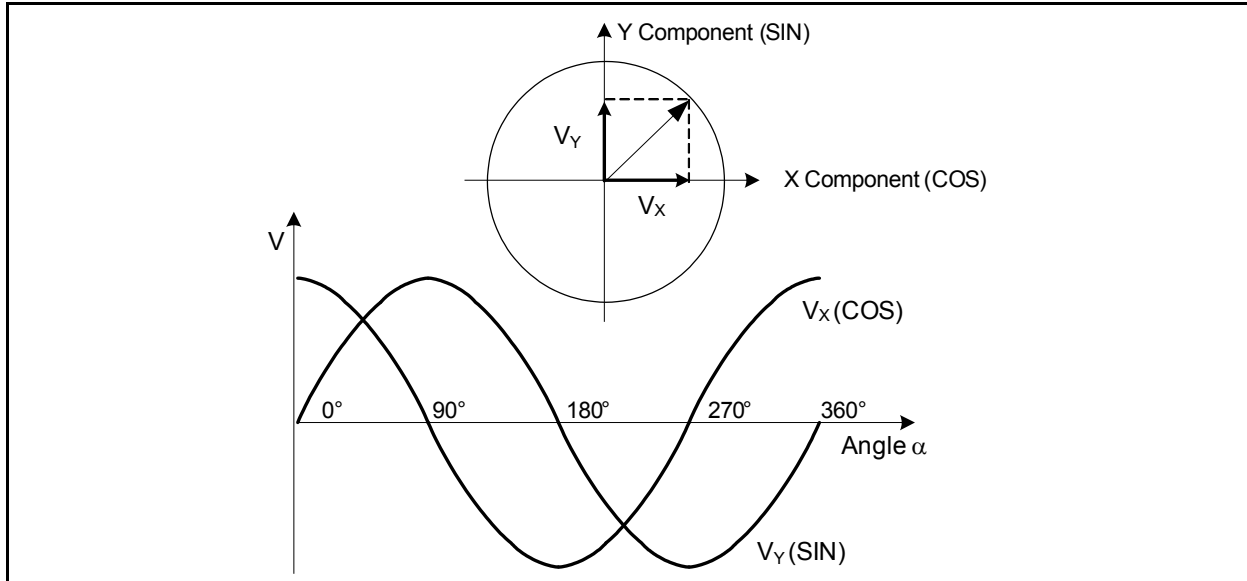


Figure 2 Ideal Output of the GMR Sensor Bridges

2.2 Pin Configuration

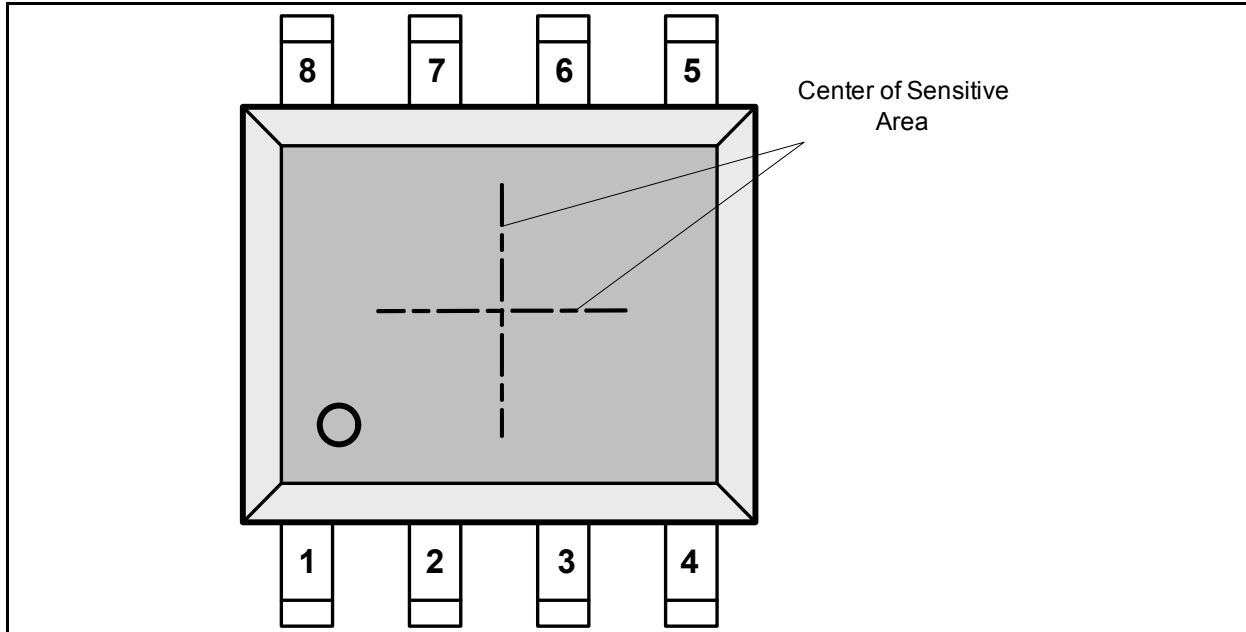


Figure 3 Pin Configuration (Top View)

2.3 Pin Description

Table 1 Pin Description

Pin No.	Symbol	In/Out	Function
1	CLK	I	External Clock (must be connected to GND for PWM output)
2	SCK	I	SSC Clock
3	CSQ	I	SSC Chip Select
4	DATA / HS3	I/O	SSC Data / IIF Index / Hall Switch Signal 3
5	IFA (IIF_A / HS1 / PWM)	O	Interface A: IIF Phase A; Hall Switch Signal 1 or PWM output (depends on external application circuit)
6	V _{DD}	-	Supply Voltage
7	GND	-	Ground
8	IFB (IIF_B / HS2)	O	Interface B: IIF Phase B or Hall Switch Signal 2

2.4 Block Diagram

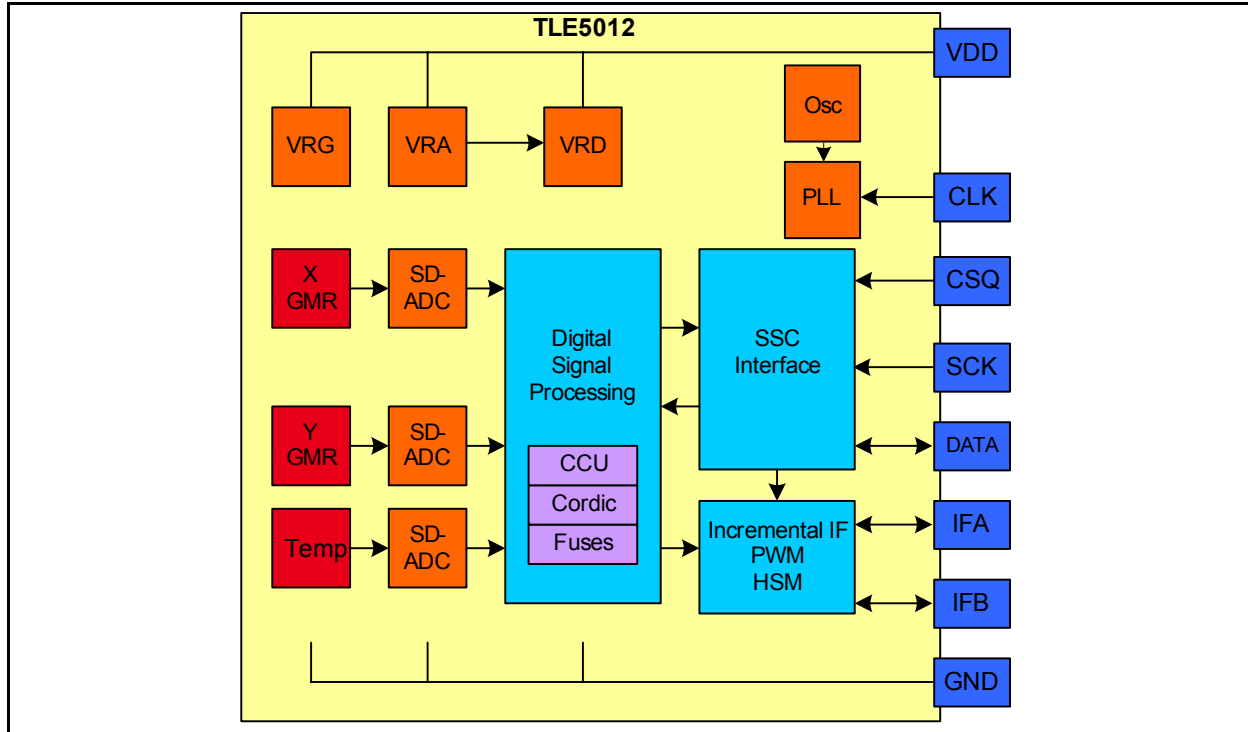


Figure 4 TLE5012 Block Diagram

2.5 Functional Block Description

2.5.1 Internal Power Supply

The internal stages of the TLE5012 are supplied with different voltage regulators.

- GMR Voltage Regulator VRG
- Analog Voltage Regulator VRA
- Digital Voltage Regulator VRD (derived from VRA)

These regulators are directly connected to the supply voltage V_{DD} .

2.5.2 Oscillator and PLL

The internal frequency oscillator feeds the Phase Locked Loop (PLL). Also the external clock (CLK) can be used therefore.

2.5.3 SD-ADC

The SD-ADCs transform the analog GMR-voltages and temperature-voltage into the digital domain.

2.5.4 Digital Signal Processing Unit

The Digital Signal Processing Unit (DSPU) contains the:

- **C**apture **C**ompare **U**nit (**CCU**), which is used to generate the PWM signal
- **C**Oordinate **R**otation **D**igital **C**omputer (**CORDIC**), which contains the trigonometric function for angle calculation
- Fuses, which contain the calibration parameters

2.5.5 Interfaces

Different Interfaces can be selected:

- SSC Interface
- PWM
- Incremental Interface
- Hall Switch Mode

2.5.6 Safety Features

The TLE5012 offers a multiplicity on safety features to support Safety Integrity Level (SIL). Sensors with this performance are identified by the following logo:



Figure 5 PRO-SIL™ Logo

Safety features are:

- Test vectors switchable to ADC- input
- Inversion or combination of filter input streams
- Data transmission check via 8bit **C**yclic **R**edundancy **C**heck (**CRC**)
- Self test routines
- Two independent active interfaces possible
- Overvoltage and undervoltage detection

3 Specification

3.1 Application Circuit

The application circuit in **Figure 6**, **Figure 7**, **Figure 8** and **Figure 9** show the different communication possibilities of TLE5012.

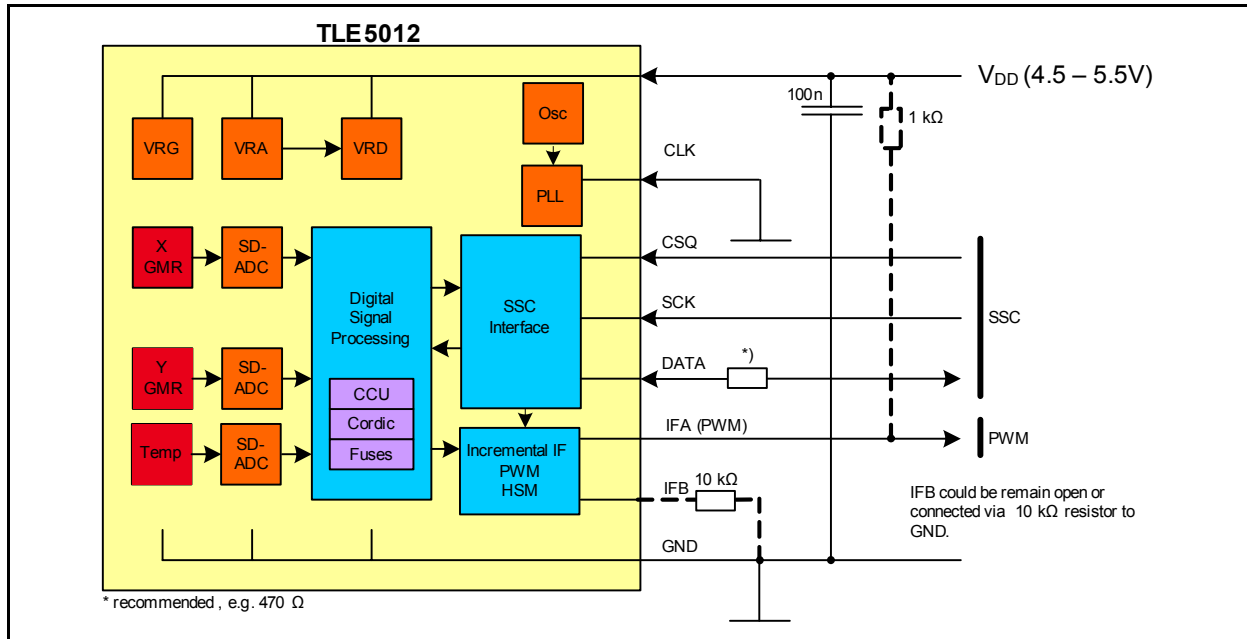


Figure 6 Application Circuit for TLE5012 with SSC and PWM Interface (using internal CLK)

Figure 6 shows a basic block-diagram of the TLE5012 with PWM- Interface. This interface is selectable by connecting CLK to GND. Additionally to the PWM the SSC Interface could be used. Within the SSC- Interface the PWM mode is selectable between Push-Pull and Open Drain.

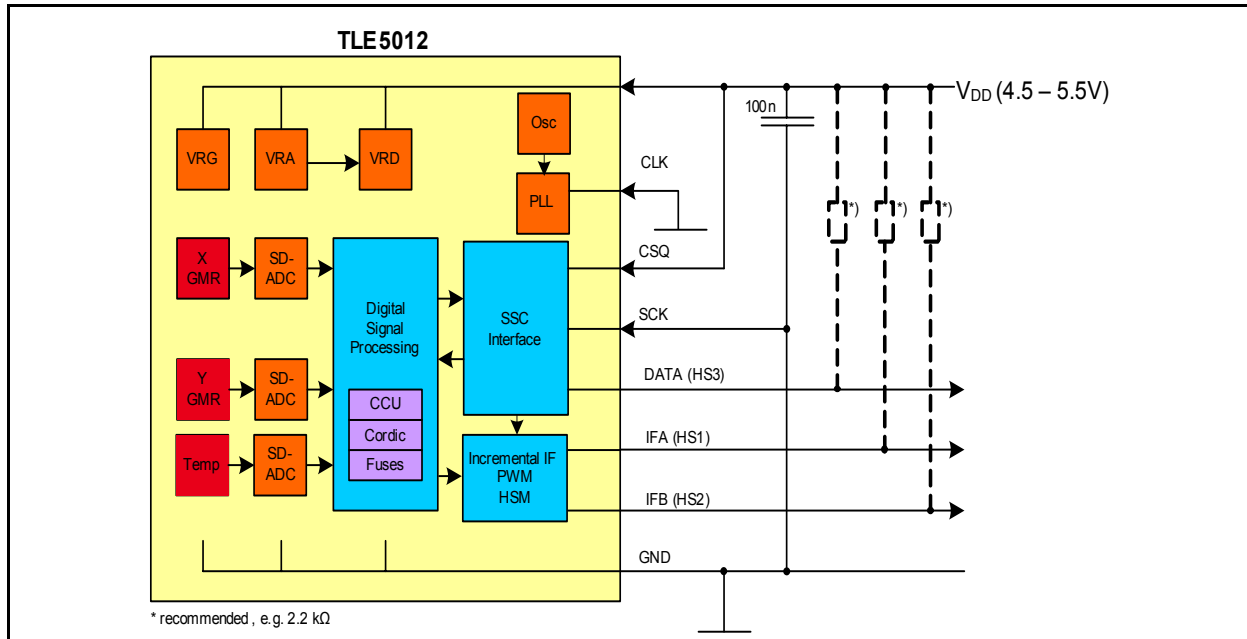


Figure 7 Application Circuit for TLE5012 with HS Mode (using internal CLK)

Figure 7 shows a basic block-diagram of the TLE5012 with HS Mode. This interface is selectable by connecting CLK to GND and CSQ to V_{DD} . Additionally to the HSM the SSC Interface could be used by pulling CSQ to GND. Within the SSC-Interface the HS Mode is selectable between Push-Pull and Open Drain.

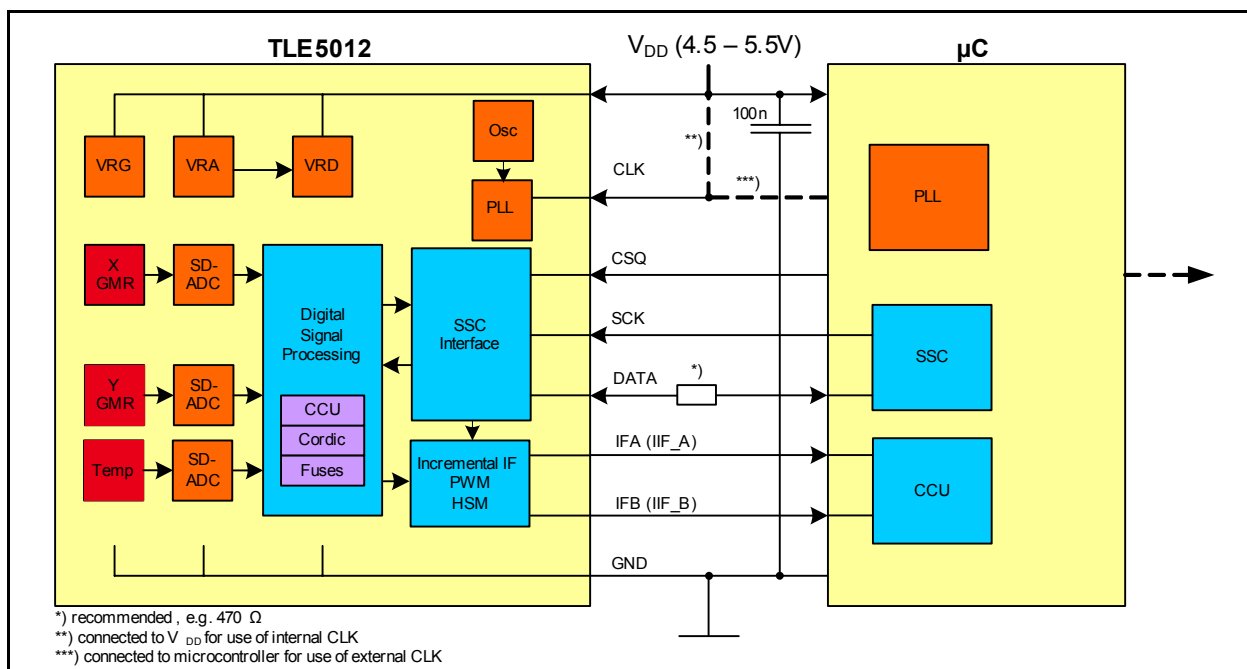


Figure 8 Application Circuit for TLE5012 with SSC and IIF Interface (using external CLK)

Figure 8 shows a basic block-diagram of an angle sensor system using a TLE5012 and a microcontroller for rotor positioning applications. The depicted Interface-Configuration is needed for High-Speed applications like electrical commutated motor drives. It is possible to connect the TLE5012 to a microcontroller via Incremental Interface and for safety reasons also via SSC-Interface.

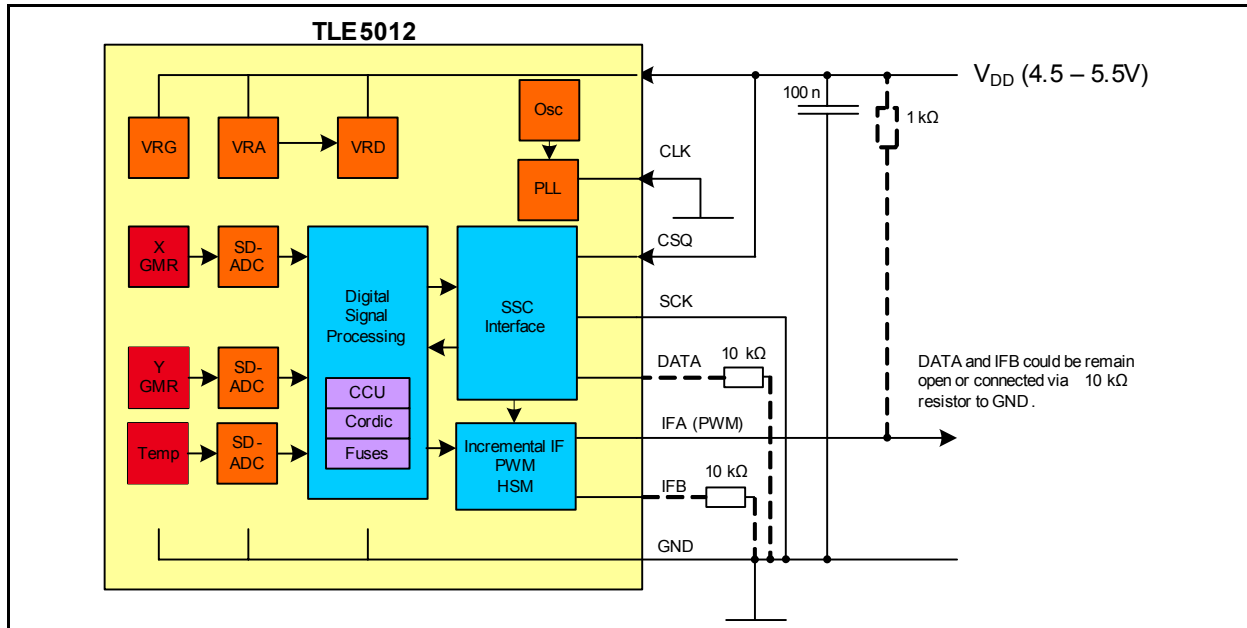


Figure 9 Application Circuit for TLE5012 with only PWM Interface (using internal CLK)

3.2 Absolute Maximum Ratings

Table 2 Absolute Maximum Ratings

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Voltage on V _{DD} pin respect to ground (V _{SS})	V _{DD}	-0.5	-	6.5	V	max 40 h/Lifetime
Voltage on any pin respect to ground (V _{SS})	V _{IN}	-0.5	-	6.5	V	additionally V _{DD} + 0.5 V may not be exceeded
Junction Temperature	T _J	-40	-	150	°C	
		-	-	150		for 1000h not additive
Magnetic Field Induction	B	-	-	125	mT	max. 5 min @ t _A = 25°C
		-	-	100		max. 5 h @ t _A = 25°C
Storage Temperature	T _{ST}	-40	-	150	°C	

Attention: Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the device.

3.3 Operating Range

The following operating conditions must not be exceeded in order to ensure correct operation of the TLE5012. All parameters specified in the following sections refer to these operating conditions, unless otherwise noticed.

Table 3 Operating Range

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Supply Voltage	V _{DD}	4.5	5.0	5.5	V	1)
Output Current (DATA-Pad)	I _Q	-	-	-25	mA	PAD_DRV = '0x', sink current ²⁾
		-	-	-5		PAD_DRV = '10', sink current ²⁾
		-	-	-0.4		PAD_DRV = '11', sink current ²⁾
Output Current (IFA / IFB-Pad)	I _Q	-	-	-15	mA	PAD_DRV = '0x', sink current ²⁾
		-	-	-5		PAD_DRV = '1x', sink current ²⁾
Input Voltage	V _{IN}	-0.3	-	5.5	V	V _{DD} + 0.3 V may not be exceeded
Magnetic Induction	B _{XY}	30	-	50	mT	in X/Y direction ³⁾
Angle Range	Ang	0	-	360	°	

1) Directly blocked with 100nF ceramic capacitor

2) Max. current to GND over Open Drain Output

3) Values refer to an homogenous magnetic field (B_{XY}) without vertical magnetic induction (B_Z = 0mT).

Note: The thermal resistances listed in [Table 20 "Package Parameters" on Page 54](#) must be used to calculate the corresponding ambient temperature. [Table 3](#) is valid for -40°C < T_J < 150°C.

Calculation of the Junction Temperature

The total power dissipation P_{TOT} of the chip increases its temperature above the ambient temperature.

The power multiplied by the total thermal resistance R_{thJA} (Junction to Ambient) leads to the final junction temperature. R_{thJA} is the sum of the addition of the values of the two components *Junction to Case* and *Case to Ambient*.

$$R_{thJA} = R_{thJC} + R_{thCA} \quad (1)$$

$$T_J = T_A + \Delta T$$

$$\Delta T = R_{thJA} \times P_{TOT} = R_{thJA} \times (V_{DD} \times I_{DD} + V_{OUT} \times I_{OUT}) \quad (I_{DD}, I_{OUT} > 0, \text{ if direction is into IC})$$

Example (assuming no load on V_{out}):

$$V_{DD} = 5V \quad (2)$$

$$I_{DD} = 12mA$$

$$\Delta T = 150 \left[\frac{K}{W} \right] \times 5[V] \times 0.012[A] + 0[VA] = 9K$$

For moulded sensors, the calculation with R_{thJC} is more adequate.

3.4 Characteristics

3.4.1 Electrical Parameters

The indicated electrical parameters apply to the full operating range, unless otherwise specified. The typical values correspond to a supply voltage $V_{DD} = 5.0\text{ V}$ and $25\text{ }^\circ\text{C}$, unless individually specified. All other values correspond to $-40\text{ }^\circ\text{C} < T_J < 150\text{ }^\circ\text{C}$.

Table 4 Electrical Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Supply Current	I_{DD}	-	12	13	mA	
POR Level	V_{POR}	2.0	-	2.9	V	Power On Reset
POR Hysteresis	V_{PORhy}	-	30	-	mV	
Power On Time	t_{Pon}	-	4	5	ms	$V_{DD} > V_{DDmin}^{1)}$
Input Signal Low Level	V_L	-	-	$0.3 V_{DD}$	V	
Input Signal High Level	V_H	$0.7 V_{DD}$	-	-	V	
Pull-Up Current	I_{PU}	-10	-	-225	μA	CSQ
		-10	-	-150		DATA
Pull-Down Current	I_{PD}	10	-	225	μA	SCK
		10	-	150	μA	CLK, IFA, IFB
Output Signal Low Level	V_{OL}	-	-	1	V	DATA; $I_Q = -25\text{ mA}$ (PAD_DRV='0x'), $I_Q = -5\text{ mA}$ (PAD_DRV='10'), $I_Q = -0.4\text{ mA}$ (PAD_DRV='11')
		-	-	1		IFA,IFB; $I_Q = -15\text{ mA}$ (PAD_DRV='0x'), $I_Q = -5\text{ mA}$ (PAD_DRV='1x')

1) Within "Power On Time" write access is not permitted

3.4.2 ESD Protection

Table 5 ESD Protection

Parameter	Symbol	Values		Unit	Notes
		min.	max.		
ESD Voltage	V_{HBM}	-	± 2.0	kV	Human Body Model ¹⁾
	V_{SDM}	-	± 0.5	kV	Socketed Device Model ²⁾

1) Human Body Model (HBM) according to: JEDEC EIA/JESD22-A114-B

2) Socketed Device Model (SDM) according to: ESD ASS.STD.DS5.3-93

3.4.3 GMR Parameters

All parameters apply over the full operating range, unless otherwise specified.

Table 6 Basic GMR Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
X, Y output range	RG _{ADC}	-	-	±23230	digits	
X, Y amplitude ¹⁾	A _X , A _Y	6000	9500	15781	digits	at calibration conditions
		3922	-	20620		operating range
X, Y synchronism ²⁾	k	87.5	100	112.49	%	at calibration conditions
X, Y offset ³⁾	O _X , O _Y	-2048	0	+2047	digits	at calibration conditions
X, Y orthogonality error	j	-11.25	0	+11.24	°	at calibration conditions
X, Y without field	X ₀ , Y ₀	-5000	-	+5000	digits	without magnet ⁴⁾

1) see [Figure 10](#)

2) $k = 100 \cdot (A_X / A_Y)$

3) $O_Y = (Y_{MAX} + Y_{MIN}) / 2$; $O_X = (X_{MAX} + X_{MIN}) / 2$

4) Not tested

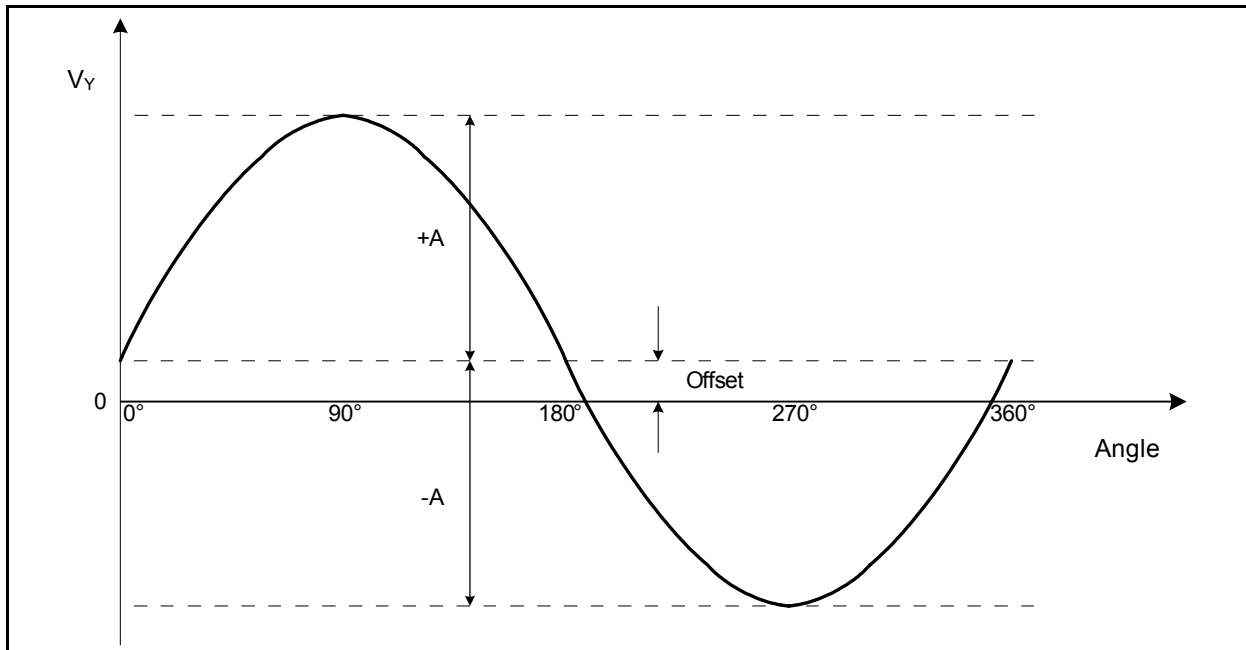


Figure 10 Offset and Amplitude Definition

3.4.4 Angle Performance

After internal calculation the sensor has a remaining error, as shown in [Table 7](#). The error value refers to $B_z = 0\text{mT}$ and the operating conditions given in [Table 3 “Operating Range” on Page 17](#).

The overall angle error represents the relative angle error. This error describes the deviation to the reference line after zero angle definition.

Table 7 Angle Performance

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Overall Angle Error (with auto-calibration)	α_{Err}	-	0.6 ¹⁾	1.0	°	including lifetime and temperature drift ²⁾³⁾
Overall Angle Error (without auto-calibration)	α_{Err}	-	0.6 ¹⁾	1.6	°	including temperature drift ²⁾³⁾

1) At 25°C, B = 30 mT

2) Including hysteresis error, caused by revolution direction change.

3) Only with calibrated GMR-compensation parameters of customer setup; Relative error after zero angle definition.

Autocalibration

The autocalibration enables online parameter calculation and reduces therefore the angle error due to misalignments.

After start-up the parameters out of the fuses get loaded into flip-flops. The TLE5012 updates these parameters after a full revolution. The update can be chosen within the Autocalibration Mode (AUTOCAL) bit. It is possible to do the update after every 22.5°, 11.25° or after t_{upd} .

3.4.5 Signal Processing

The signal path of the TLE5012 is depicted in [Figure 11](#). It consists of the GMR-bridge, ADC, filter and angle calculation. Depending on the filter configuration a different total delay time is achieved. Additional to this delay time, the delay time of the interface has to be considered. The delay time leads to an additional angle error at higher speeds. With enabling the prediction, the signal delay time will be reduced ([Figure 12](#)).

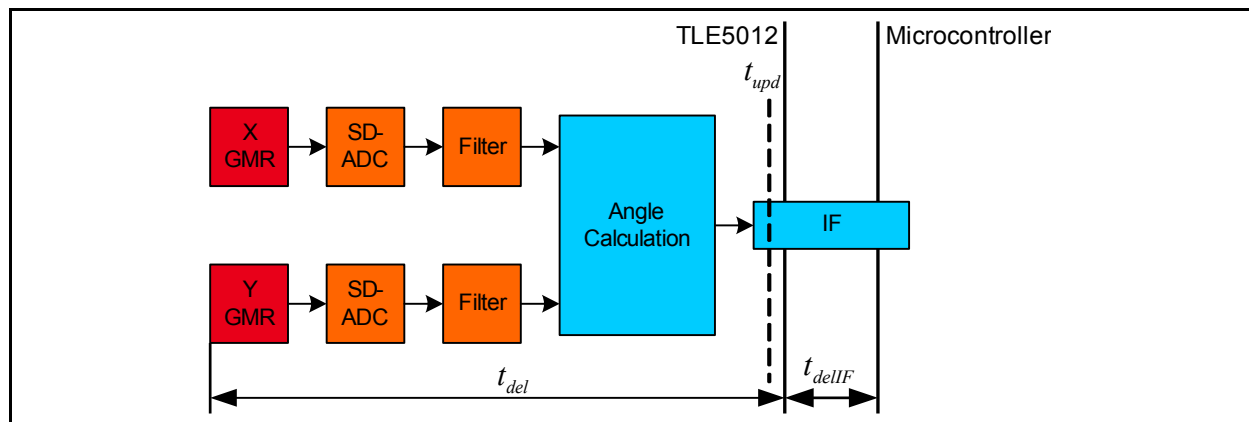


Figure 11 TLE5012 Signal path

At $FIR_MD = 0$ only raw values can be read out, due to the more time consuming angle calculation.

Table 8 Signal Processing

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Update Rate at Interface	t_{upd}	-	21.3	-	μs	FIR_MD = 0 (only raw values) ¹⁾²⁾
		-	42.7	-		FIR_MD = 1 ¹⁾²⁾
		-	85.3	-		FIR_MD = 2 (default) ¹⁾²⁾
		-	170.6	-		FIR_MD = 3 ¹⁾²⁾
Angle Delay Time ³⁾	t_{del}	-	60	70	μs	FIR_MD = 1 ¹⁾²⁾
		-	80	95		FIR_MD = 2 ¹⁾²⁾
		-	120	140		FIR_MD = 3 ¹⁾²⁾
Angle Noise	N_{Angle}	-	0.11	-	$^{\circ}$	FIR_MD = 0, (1 Sigma) ²⁾
		-	0.08	-		FIR_MD = 1, (1 Sigma) ²⁾
		-	0.05	-		FIR_MD = 2, (1 Sigma) ²⁾ (default)
		-	0.04	-		FIR_MD = 3, (1 Sigma) ²⁾

1) depends on internal oscillator frequency variation ([Chapter 3.4.6](#))

2) guaranteed by laboratory characterization

3) valid at constant rotation speed

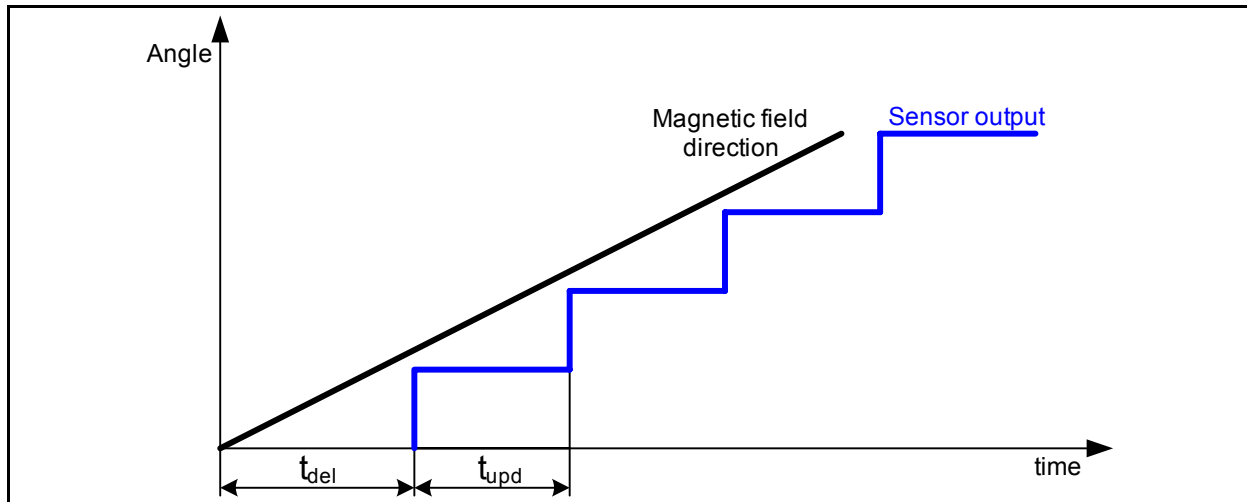


Figure 12 Delay of Sensor Output

3.4.6 Clock Supply (CLK Timing Definition)

If the external clock supply is selected, the clock signal input 'CLK' must fulfill certain requirements which are described in the following:

- The high or low pulse width must not exceed the specified values, because the PLL needs a minimum pulse width and must be spike filtered.
- The duty cycle factor should be 0.5 but can deviate to the values limited by $t_{CLKh(f_min)}$ and $t_{CLKl(f_min)}$.
- The PLL is triggered at the positive edge of the clock. If more than 2 edges are missing, a chip reset is generated automatically.

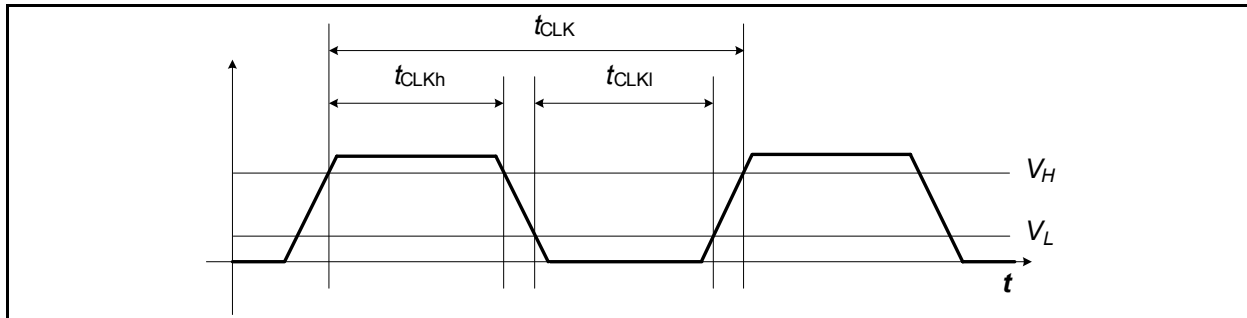


Figure 13 External CLK Timing Definition

Table 9 CLK Timing Specification

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input Frequency	f_{CLK}	3.8	4.0	4.2	MHz	
CLK Duty Cycle ¹⁾²⁾	CLK_{DUTY}	30	50	70	%	
CLK Rise Time	t_{CLKr}	-	-	30	ns	from V_L to V_H
CLK Fall Time	t_{CLKf}	-	-	30	ns	from V_H to V_L
Digital Clock	f_{DIG}	22.8	24	25.2	MHz	
Internal Oscillator Frequency	f_{CLK}	3.8	4.0	4.2	MHz	

1) Minimum Duty Cycle Factor: $t_{CLKh(f_min)} / t_{CLK(f_min)}$ with $t_{CLK(f_min)} = 1 / f_{CLK(f_min)}$

2) Maximum Duty Cycle Factor: $t_{CLKh(f_max)} / t_{CLK(f_min)}$ with $t_{CLKh(f_max)} = t_{CLK(f_min)} - t_{CLKl(min)}$

Another possibility is a 3-pin SSC Interface with bidirectional open-drain data line, serial clock signal and chip select. This setup is designed to communicate with a microcontroller in a bus system, together with other SSC slaves (e.g. two TLE5012 for redundancy reasons). This mode can be activated using bit SSC_OD.

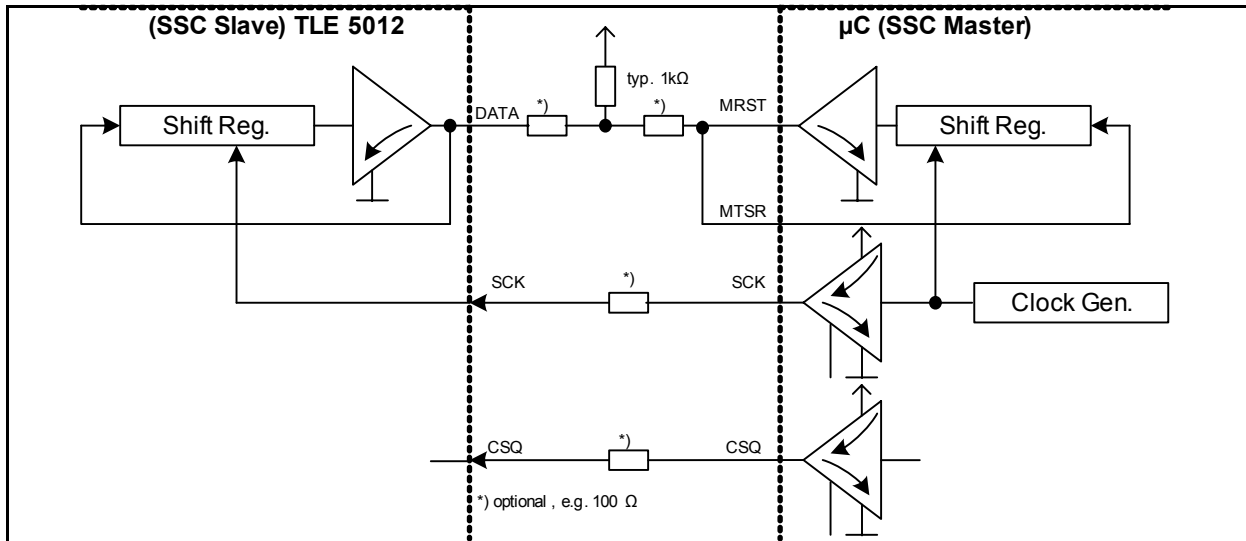


Figure 15 SSC Configuration in Sensor-Slave Mode and Open Drain (Safe Bus Systems)

3.5.1.1 SSC Timing Definition

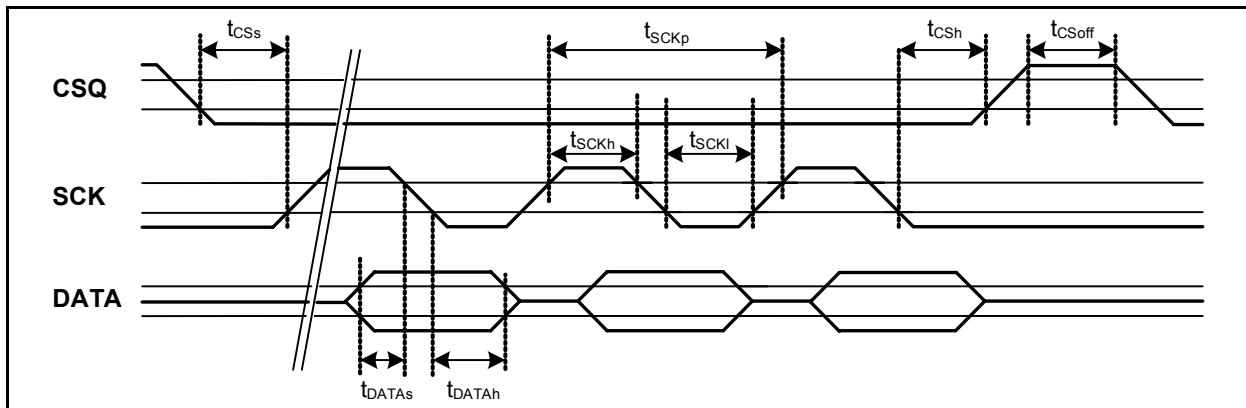


Figure 16 SSC Timing

SSC Inactive Time (CS_{off})

The SSC inactive time defines the delay time after a transfer before the TLE5012 can be selected again.

Table 11 SSC Push-Pull Timing Specification

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
SSC Baud Rate	f _{SSC}	-	8.0	-	Mbit/s	
CSQ Setup Time	t _{CSs}	105	-	-	ns	
CSQ Hold Time	t _{CSh}	105	-	-	ns	

Table 11 SSC Push-Pull Timing Specification (cont'd)

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
CSQ off	t_{CSoff}	600	-	-	ns	SSC inactive time
SCK Period	t_{SCKp}	120	125	-	ns	
SCK High	t_{SCKh}	40	-	-	ns	
SCK Low	t_{SCKl}	30	-	-	ns	
DATA Setup Time	t_{DATA_s}	25	-	-	ns	
DATA Hold Time	t_{DATA_h}	40	-	-	ns	
Write Read Delay	t_{wr_delay}	130	-	-	ns	

Table 12 SSC Open Drain Timing Specification

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
SSC Baud Rate	f_{SSC}	-	2.0	-	Mbit/s	Pull-up Resistor = 1k Ω
CSQ Setup Time	t_{CSs}	300	-	-	ns	
CSQ Hold Time	t_{CS_h}	400	-	-	ns	
CSQ off	t_{CSoff}	600	-	-	ns	SSC inactive time
SCK Period	t_{SCKp}	500	-	-	ns	
SCK High	t_{SCKh}	-	190	-	ns	
SCK Low	t_{SCKl}	-	190	-	ns	
DATA Setup Time	t_{DATA_s}	25	-	-	ns	
DATA Hold Time	t_{DATA_h}	40	-	-	ns	
Write Read Delay	t_{wr_delay}	130	-	-	ns	

3.5.1.2 SSC Data Transfer

The SSC data transfer is word aligned. The following transfer words are possible:

- Command word (to access and change operating modes of the TLE5012)
- Data words (any data transferred in any direction)
- Safety word (confirms the data transfer and provide status information)

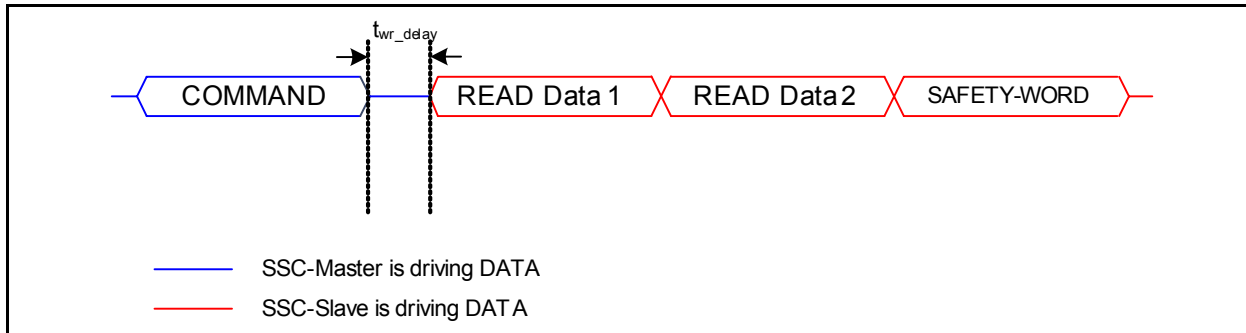


Figure 17 SSC Data Transfer (Data Read Example)

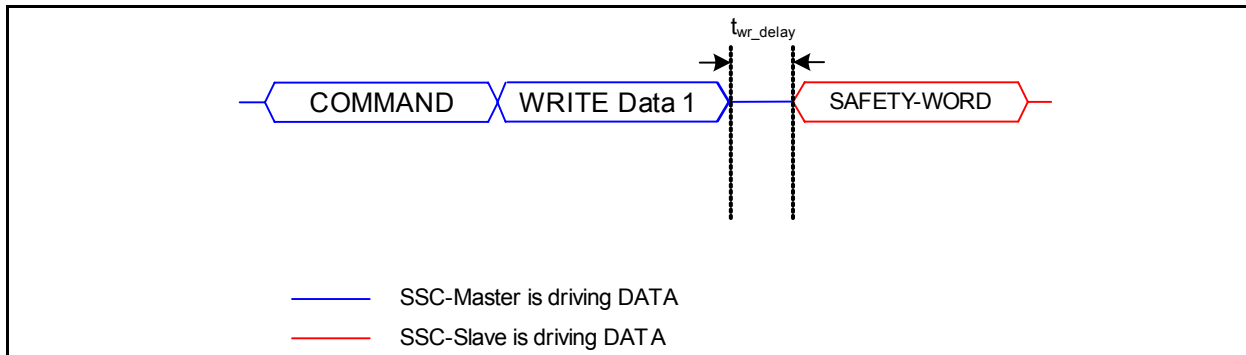


Figure 18 SSC Data Transfer (Data Write Example)

Command Word

The TLE5012 is controlled by a command word. It is sent first at every data transmission.

Table 13 Structure of the Command Word

Name	Bits	Description
RW	[15]	Read - Write 0:Write 1:Read
Lock	[14..11]	4 bit Lock Value 0x00: Default Operating Access 0x02: Config- Access
UPD	[10]	Update-Register Access 0: Access to current values 1: Access to updated values
ADDR	[9..4]	6 bit Address
ND	[3..0]	4 bit Number of Data-Words

Safety Word

The safety word contains following bits:

Table 14 Structure of the Safety Word

Name	Bits	Description
STAT	Chip and Interface Status	
	[15]	Indication of Chip-Reset (resets after readout) via SSC 0: No reset 1: Reset occurred Reset: 0 _B
	[14]	System Error (e.g. Overvoltage; Undervoltage; V _{DD} - off; GND- off; ROM;...) 0: No error 1: Error occurred (S_VR; S_DSPU; S_OV; S_XYOL: S_MAGOL; S_ADCM)
	[13]	Interface Access Error (access to wrong address; wrong lock) 0: No error 1: Error occurred
	[12]	Valid Angle Value (no system error; no interface error; NO_GMR_A = '0'; NO_GMR_XY='0') 0: Angle value valid 1: Angle value invalid
RESP	[11..8]	Sensor Number Response Indicator The sensor no. bit is pulled low and the other bits are high.
CRC	[7..0]	Cyclic Redundancy Check (CRC)

Data Communication via SSC

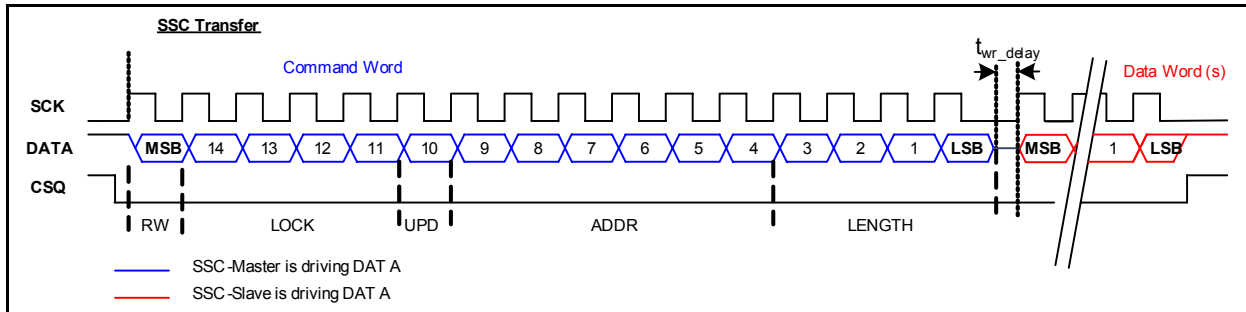


Figure 19 SSC Bit Ordering (Read Example)

The data communication via SSC interface has the following characteristic:

- The data transmission order is “Most Significant Bit (MSB) first”.
- Data is put on the data line with the rising edge on SCK and read with the falling edge on SCK.
- The SSC Interface is word-aligned. All functions are activated after each transmitted word.
- A “high” condition on the negated Chip Select pin (CSQ) of the selected TLE5012 interrupts the transfer immediately. The CRC calculator is automatically reset.
- After changing the data direction, a delay (t_{wr_delay}) has to be considered before continuing the data transfer. This is necessary for internal register access.
- Every access to the TLE5012 with the number of data (ND) ≥ 1 is performed with address auto-increment.
- At an overflow at address $3F_H$ the transfer continuous at address 00_H .
- With ND = 0 no auto-increment is done and a continuously readout of the same address can be realized. Afterwards no Safety Word is send and the transfer ends with high condition on CSQ.
- After every data transfer with ND ≥ 1 the 16 bit Safety Word will be appended by the selected TLE5012.
- At a rising edge of CSQ without data transfer before (no SCK-pulse), the update-registers are updated with according values.
- After sending the Safety Word the transfer ends. To start another data transfer, the CSQ has to be deselected once for t_{CSoff} .
- The SSC is default Push-Pull. The Push-Pull driver is only active, if the TLE5012 has to send data, otherwise the Push-Pull is disabled for receiving data from the microcontroller.

Cyclic Redundancy Check (CRC)

- This CRC is according to the J1850 Bus-Specification.
- Every new transfer resets the CRC generation.
- Every Byte of a transfer will be taken into account to generate the CRC (also the sent command(s)).
- Generator-Polynomial: $X^8+X^4+X^3+X^2+1$, but for the CRC generation the fast-CRC generation circuit is used (see Figure 20)
- The remainder of the fast CRC circuit is initial set to '11111111_B'.
- Remainder is inverted before transmission.

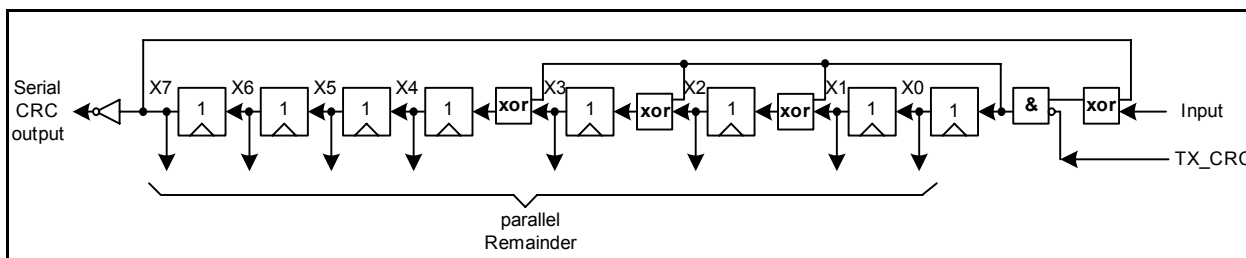


Figure 20 Fast CRC Polynomial Division Circuit

3.5.1.3 Registers Chapter

This chapter defines the registers of the TLE5012. It also defines the read/write access rights of the specific registers. **Table 15** identifies the values with symbols. Access to the registers is accomplished via the SSC Interface.

Table 15 Registers Overview

Register Short Name	Register Long Name	Offset Address	Page Number
Registers Chapter, TLE5012 Register			
STAT	Status Register	00 _H	31
ACSTAT	Activation Status Register	01 _H	33
AVAL	Angle Value Register	02 _H	34
ASPD	Angle Speed Register	03 _H	35
AREV	Angle Revolution Register	04 _H	35
FSYNC	Frame Synchronization Register	05 _H	36
MOD_1	Interface Mode1 Register	06 _H	37
SIL	SIL Register	07 _H	38
MOD_2	Interface Mode2 Register	08 _H	39
MOD_3	Interface Mode3 Register	09 _H	40
OFFX	Offset X	0A _H	41
OFFY	Offset Y	0B _H	42
SYNCH	Synchronicity	0C _H	42
IFAB	IFAB Register	0D _H	43
MOD_4	Interface Mode4 Register	0E _H	44
TCO_Y	Temperature Coeffizient Register	0F _H	45
ADC_X	X-raw value	10 _H	45
ADC_Y	Y-raw value	11 _H	46

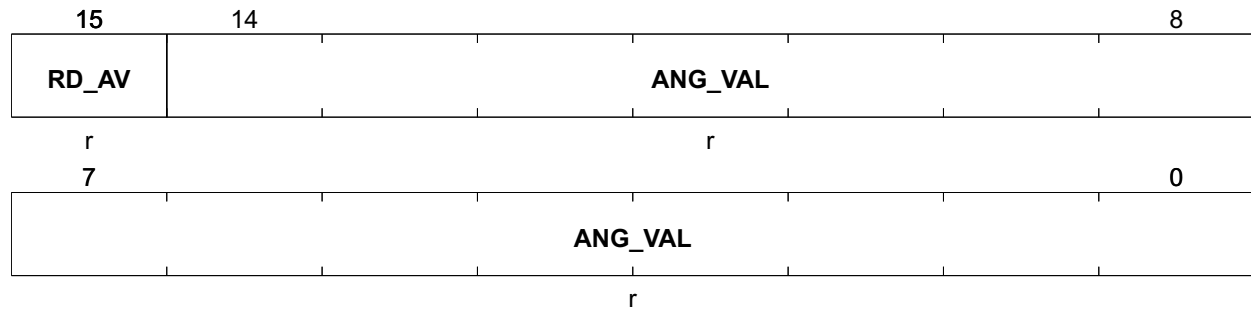
The register is addressed wordwise.

Field	Bits	Type	Description
S_XYOL	6	r	Status X,Y Data Out of Limit 0 _B after readout 1 _B X,Y data out of limit (>23230 digits) Reset: 0 _B
S_OV	5	r	Status Overflow 0 _B after readout 1 _B DSPU overflow occurred Reset: 0 _B
S_DSPU	4	r	Status Digital Signal Processing Unit 0 _B after readout 1 _B DSPU self test not ok, or selftest is running Reset: 0 _B
S_FUSE	3	r	Status Fuse CRC 0 _B after readout, Fuse CRC ok 1 _B Fuse CRC fail Reset: 0 _B
S_VR	2	r	Status Voltage Regulator 0 _B after readout 1 _B V _{DD} overvoltage; V _{DD} undervoltage; V _{DD} -off; GND-off; or V _{OVG} ; V _{OVA} ; V _{OVD} too high Reset: 0 _B
S_WD	1	r	Status Watchdog 0 _B after chip reset 1 _B watchdog counter expired Reset: 0 _B
S_RST	0	r	Status Reset 0 _B after readout 1 _B indication of power-up, short power-break or active reset Reset: 1 _B

Field	Bits	Type	Description
AS_RST	0	rw	Activation of Hardware Reset Activation occurs after CSQ switches from '0' to '1' after SSC transfer. 0 _B after execution 1 _B activation of HW Reset Reset: 0 _B

Angle Value Register

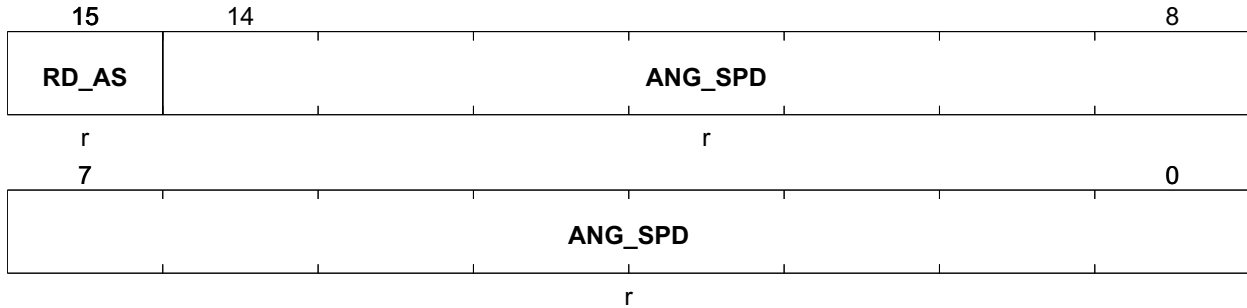
AVAL	Offset	Reset Value
Angle Value Register	02 _H	8000 _H



Field	Bits	Type	Description
RD_AV	15	r	Read Status, Angle Value 0 _B after readout 1 _B new angle value (ANG_VAL) present Reset: 1 _B
ANG_VAL	14:0	r	Calculated Angle Value (ANG_RANGE = 0x080) 4000 _H -180° 0000 _H 0° 3FFF _H +179.99° Reset: 0 _H

Angle Speed Register

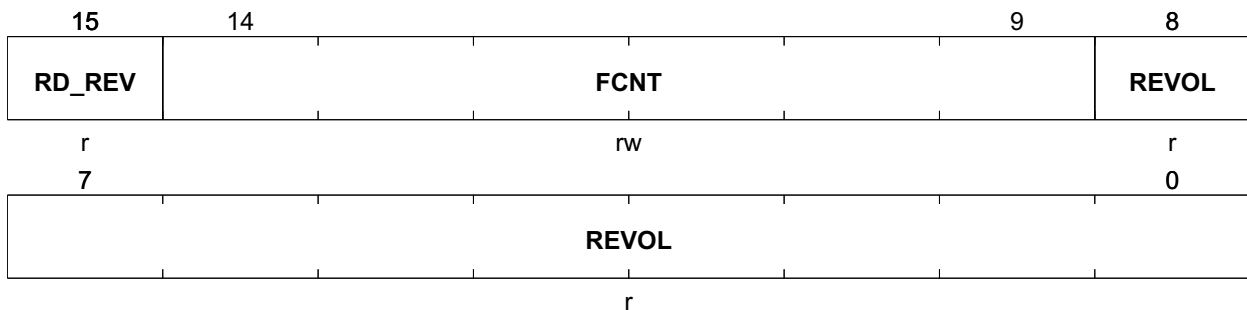
ASPD **Offset** **Reset Value**
Angle Speed Register **03_H** **8000_H**



Field	Bits	Type	Description
RD_AS	15	r	Read Status, Angle Speed 0 _B after readout 1 _B new angle speed value (ANG_SPD) present Reset: 1 _B
ANG_SPD	14:0	r	Calculated Angle Speed Without prediction difference between two consecutive angle values. With prediction, difference between three consecutive angle values. Reset: 0 _H

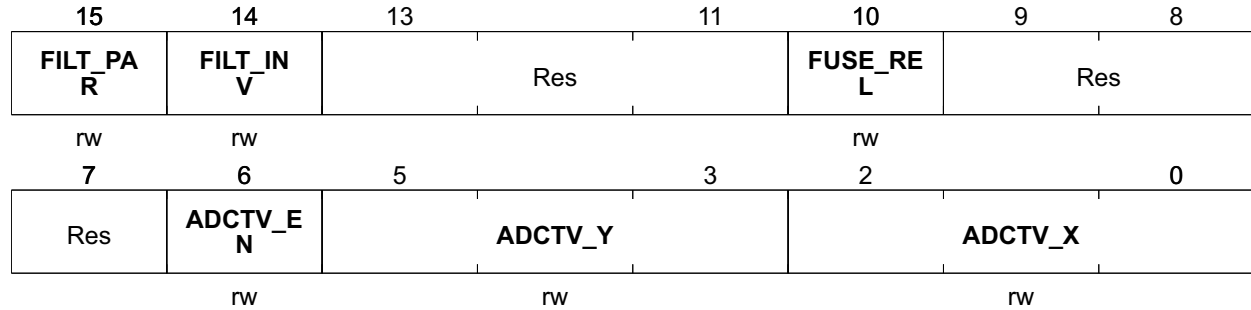
Angle Revolution Register

AREV **Offset** **Reset Value**
Angle Revolution Register **04_H** **Error in Input**



SIL Register

SIL Offset Reset Value
 SIL Register 07_H 0000_H

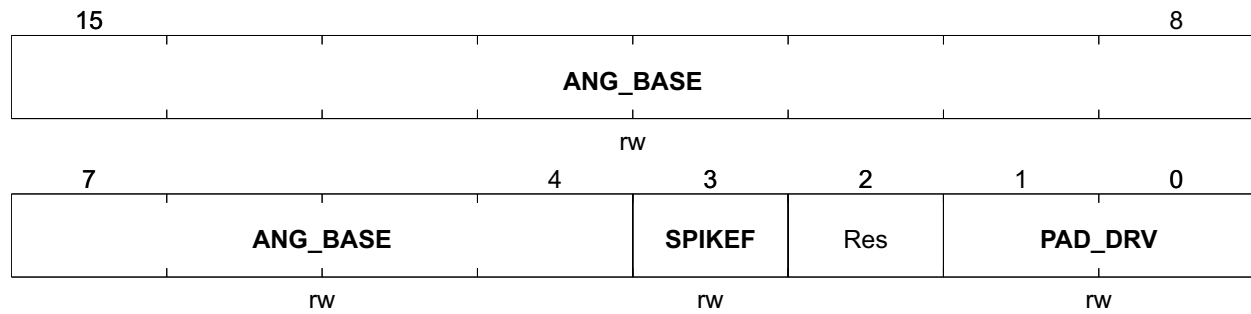


Field	Bits	Type	Description
FILT_PAR	15	rw	Filter Parallel 0 _B filter parallel disabled 1 _B filter parallel enabled (source: X-value) Reset: 0 _B
FILT_INV	14	rw	Filter Inverted 0 _B filter inverted disabled 1 _B filter inverted enabled Reset: 0 _B
FUSE_REL	10	rw	Fuse Reload 0 _B fuse reload disabled 1 _B fuse parameters reloaded to DSPU at next cycle start Reset: 0 _B
ADCTV_EN	6	rw	ADC-Test vectors 0 _B ADC-Test vectors disabled 1 _B ADC-Test vectors enabled Reset: 0 _B
ADCTV_Y	5:3	rw	Test vector Y 000 _B 0V 001 _B +70% 010 _B +100% 011 _B +Overflow 101 _B -70% 110 _B -100% 111 _B -Overflow Reset: 0 _H

Field	Bits	Type	Description
AUTOCAL	1:0	rw	Autocalibration Mode 00 _B no autocalibration 01 _B autocalibration time mode (1LSB parameter change every t_{upd}) (default within TLE5012-E0318 and TLE5012-E0742) 10 _B autocalibration angle mode1 (1LSB parameter change every 22.5°) 11 _B autocalibration angle mode2 (1LSB parameter change every 11.25°) Reset: 00 _B

Interface Mode3 Register

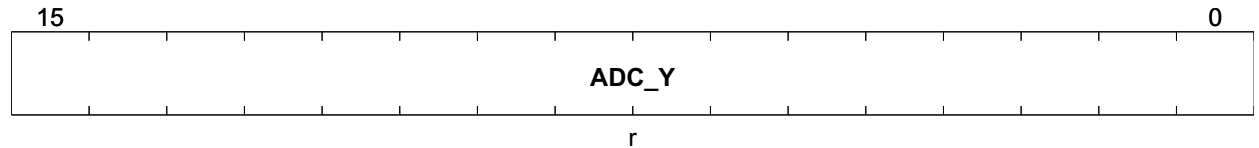
MOD_3	Offset	Reset Value
Interface Mode3 Register	09 _H	0000 _H



Field	Bits	Type	Description
ANG_BASE	15:4	rw	Angle Base 800 _H -180° 000 _H 0° 001 _H 0.00879° 7FF _H +179.912° Reset: 000 _H
SPIKEF	3	rw	Analog Spike Filters of Input Pads 0 _B spike filter disabled 1 _B spike filter enabled Reset: 0 _B

Y-row Value Register

ADC_Y	Offset	Reset Value
Y-row value	11 _H	0000 _H



Field	Bits	Type	Description
ADC_Y	15:0	r	ADC value of Y-GMR Updated when ADC_X or ADC_Y is read. Reset: 0 _H

3.5.2 Pulse Width Modulation Interface

The **Pulse Width Modulation (PWM)** Interface can be selected by connecting CLK to V_{DD}.

The PWM update rate can be programmed within the register 0E_H (IFAB_RES) in following steps:

- 0.25 kHz with 12 bit resolution
- 0.5 kHz with 11 bit resolution
- 1.0 kHz with 10 bit resolution (default)
- 2.0 kHz with 9 bit resolution

PWM uses a square wave with constant frequency whose duty cycle is modulated resulting in an average value of the waveform.

Figure 21 shows the principle behavior of a PWM with different duty cycles and the definition of timing values. The duty cycle of a PWM is defined by following general formulas:

$$\begin{aligned}
 \text{Duty Cycle} &= \frac{t_{on}}{t_{PWM}} \\
 t_{PWM} &= t_{on} + t_{off} \\
 f_{PWM} &= \frac{1}{t_{PWM}}
 \end{aligned}
 \tag{3}$$

The range between 0 - 6.25% and 93.75 - 100% is used only for diagnostic purposes. More details are given in **Table 16**.

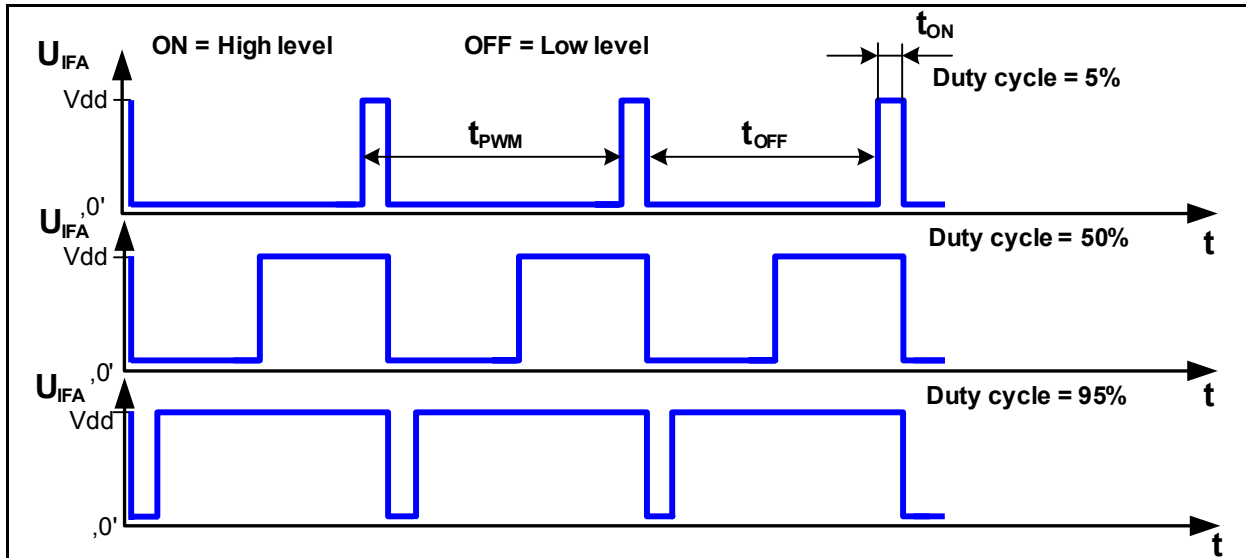


Figure 21 Typical Example for a PWM Signal

Table 16 PWM Interface

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
PWM Output Frequency	f_{PWM}	244	-	1953	Hz	selectable by IFAB_RES ¹⁾
Output Duty Cycle Range	DY_{PWM}	6.25	-	93.75	%	Absolute Angle
		-	2	-	%	Electrical Error
		-	98	-	%	System Error
		0	-	1	%	Short to GND
		99	-	100	%	Short to V _{DD} , Power-Loss
PWM Period Variation	t_{PWMvar}	-5	-	5	%	²⁾

1) $f_{PWM} = (f_{DIG} * 2^{IFAB_RES}) / (24 * 4096)$

2) depends on internal oscillator frequency variation ([Chapter 3.4.6](#))

3.5.3 Hall Switch Mode

The Hall Switch Mode (HSM) within the TLE5012 allows to emulate the output of three Hall switches. Hall switches are often used in electrical commutated motors to get information of the rotor position. With these three output signals the motor will be commutated in the right way. Depending on the used pole pairs of the rotor, different amount of electrical periods have to be realized. This is selectable within $0E_H$ (HSM_PLP). Within the TLE5012-E1218 three polepairs and within the TLE5012-E1242 seven polepairs are fused. **Figure 22** depicts the three output signals with the relationship between electrical angle and mechanical angle. The mechanical 0° point is always used as reference.

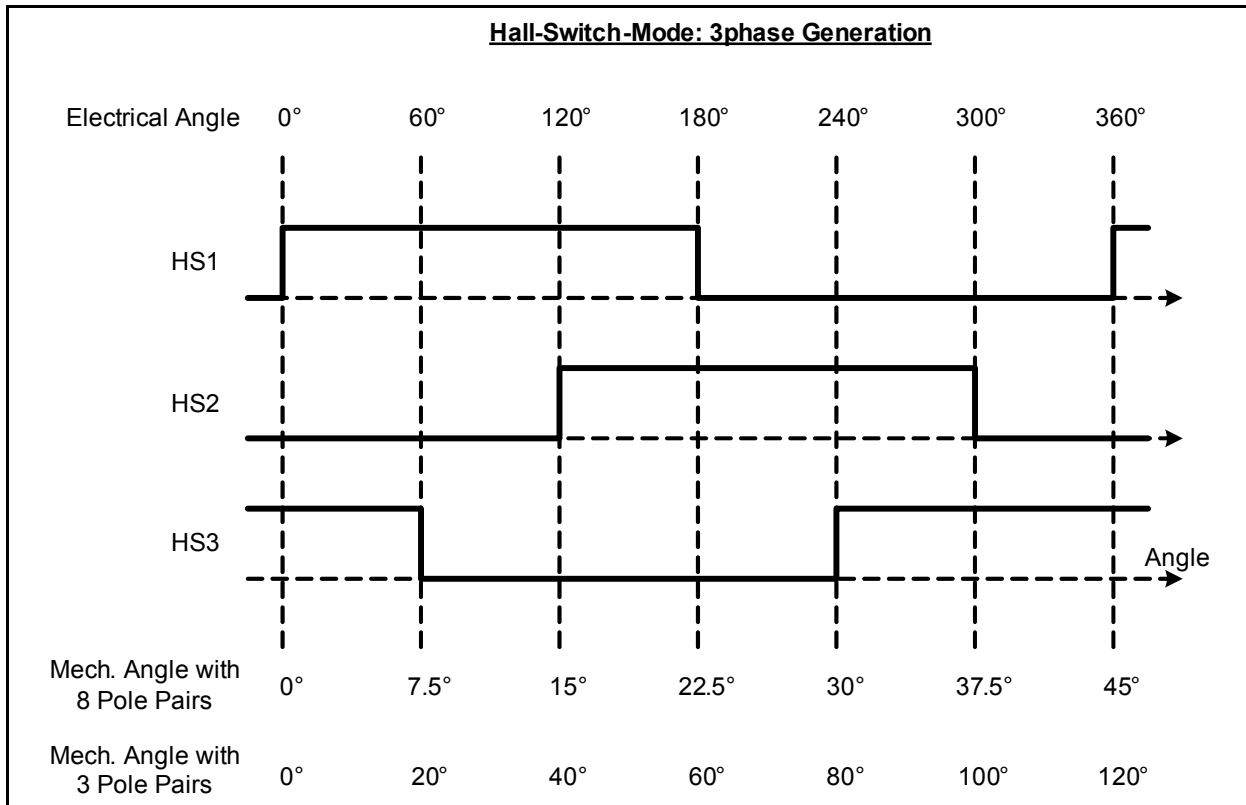


Figure 22 Hall Switch Mode

The HSM Interface can be selected by connecting CLK to GND and CSQ has to be logic "1".

Table 17 Hall Switch Mode

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Rotation Speed	n	-	-	10000	rpm	

Table 17 Hall Switch Mode

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Electrical Angle Accuracy	α_{elect}	-	1.2	2	°	2 polepairs with autocalibration ¹⁾²⁾
		-	1.8	3		3 polepairs with autocal. ¹⁾²⁾
		-	2.4	4		4 polepairs with autocal. ¹⁾²⁾
		-	3.6	6		6 polepairs with autocal. ¹⁾²⁾
		-	4.2	7		7 polepairs with autocal. ¹⁾²⁾
		-	4.8	8		8 polepairs with autocal. ¹⁾²⁾
		-	7.2	12		12 polepairs with autocal. ¹⁾²⁾
		-	9.6	16		16 polepairs with autocal. ¹⁾²⁾
Mechanical Angle Switching Hysteresis	α_{HShystm}	0	-	0.625	°	selectable by IFAB_HYST
Electrical Angle Switching Hysteresis ³⁾	α_{HShystel}	-	1.25	-	°	2 polepairs; IFAB_HYST=11 ¹⁾²⁾
		-	1.88	-		3 polepairs; IFAB_HYST=11 ¹⁾²⁾
		-	2.50	-		4 polepairs; IFAB_HYST=11 ¹⁾²⁾
		-	3.75	-		6 polepairs; IFAB_HYST=11 ¹⁾²⁾
		-	4.38	-		7 polepairs; IFAB_HYST=11 ¹⁾²⁾
		-	5.00	-		8 polepairs; IFAB_HYST=11 ¹⁾²⁾
		-	7.50	-		12 polepairs; IFAB_HYST=11 ¹⁾²⁾
		-	10	-		16 polepairs; IFAB_HYST=11 ¹⁾²⁾
Fall Time	t_{HSfall}	-	0.02	1	µs	$R_L = 2.2\text{k}\Omega; C_L < 50\text{pF}$
Rise Time	t_{HSrise}	-	0.4	1	µs	$R_L = 2.2\text{k}\Omega; C_L < 50\text{pF}$

1) depends on internal oscillator frequency variation ([Chapter 3.4.6](#))

2) guaranteed by design

3) The hysteresis has to be considered only at change of rotation direction.

To avoid switching on mechanical vibrations of the rotor, a hysteresis is recommended ([Figure 23](#)).

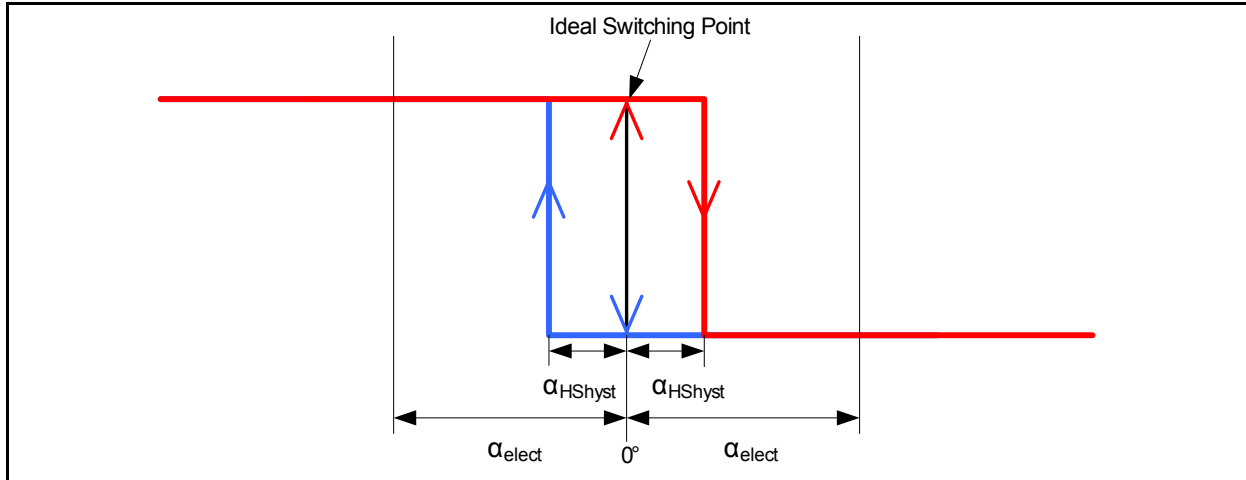


Figure 23 HS Hysteresis

3.5.4 Incremental Interface

The Incremental Interface (IIF) uses an up/down counter of a microcontroller for the angle transmission. The synchronization is done by the parallel active SSC-Interface. The angle value read out by the SSC-Interface can be compared with the stored counter value. In case of a non-synchronization, the microcontroller add the difference to the actual counter value to synchronize the TLE5012 with the microcontroller.

A/B Mode

The phase shift between phase A and B indicates a clockwise (B follows A) or a counterclockwise (A follows B) rotation of the magnet.

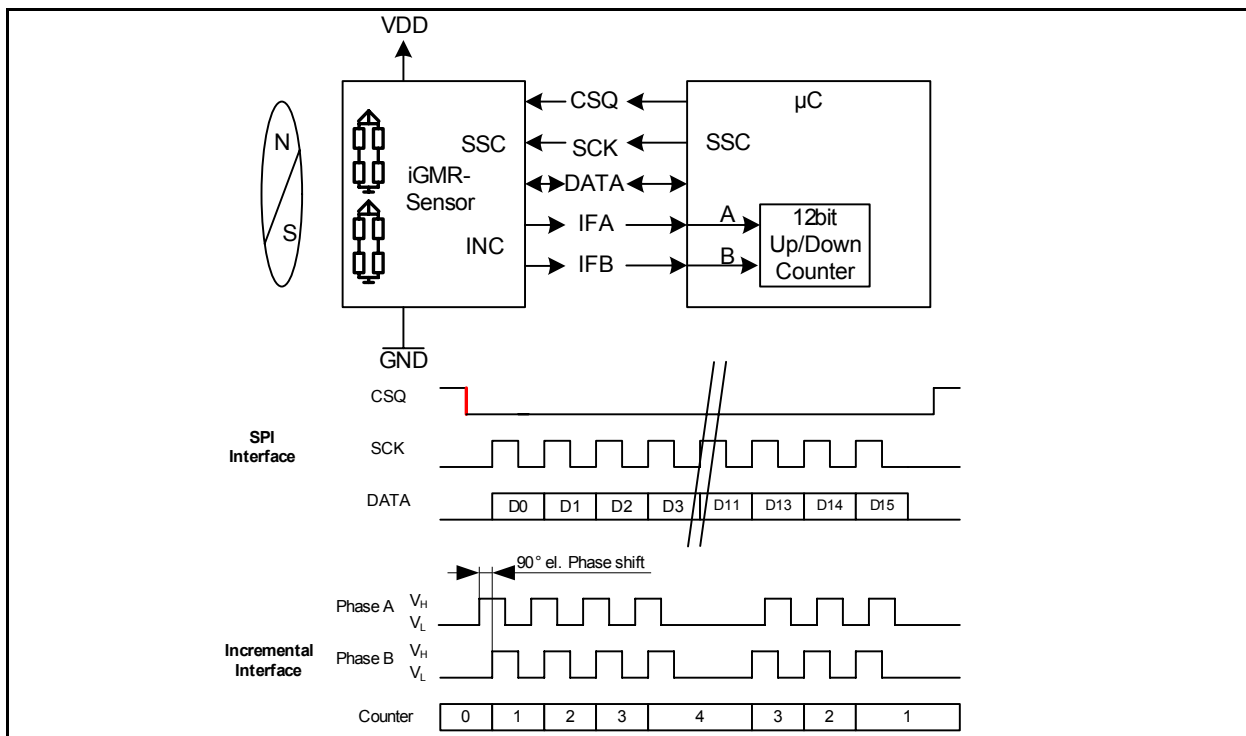


Figure 24 Incremental Interface Protocol

Index Signal

The Index-Signal is generated via Data pin, while CSQ is high (no SSC-communication). The Index-Signal is coded in quadrants via a PWM-sequence, **Figure 25**.

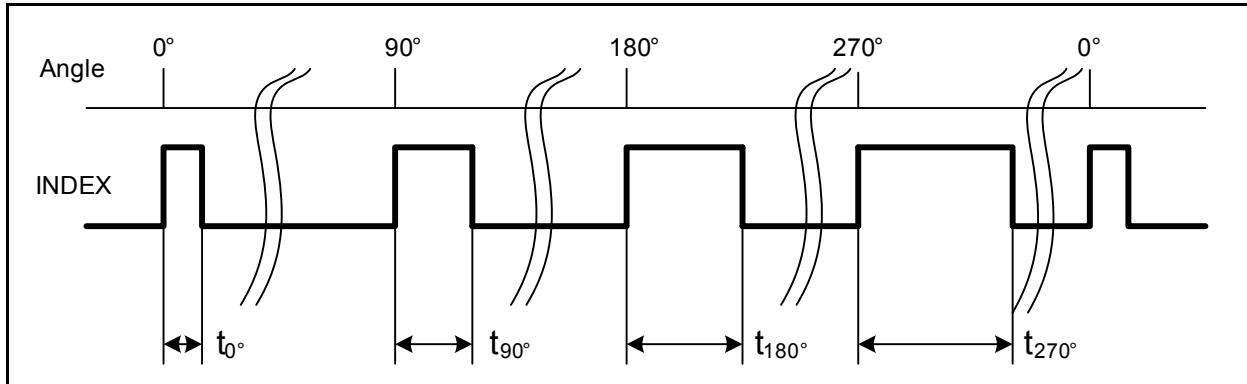


Figure 25 IIF Index Coding

Table 18 Incremental Interface

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Incremental output Frequency	f_{inc}	-	-	1.0	MHz	Frequency of Phase A and Phase B
Index	t_{0°	-	5	-	μs	0°
	t_{90°	-	10	-	μs	90°
	t_{180°	-	15	-	μs	180°
	t_{270°	-	20	-	μs	270°

3.6 Overvoltage Comparators

Various comparators monitor the voltage in order to ensure error free operation. The overvoltages must be active at least 256 periods of t_{DIG} to set the test comparator bits in the SSC Interface registers. This works as digital spike suppression.

Table 19 Test Comparators

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Overvoltage Detection	V_{OVG}	-	2.80	-	V	
	V_{OVA}	-	2.80	-	V	
	V_{OVD}	-	2.80	-	V	
V_{DD} Overvoltage	V_{DDOV}	-	6.05	-	V	
V_{DD} Undervoltage	V_{DDUV}	-	2.70	-	V	
GND - Off Voltage	V_{GNDoff}	-	-0.55	-	V	
V_{DD} - Off Voltage	V_{VDDoff}	-	0.55	-	V	
Spike Filter Delay	t_{DEL}	-	10	-	μs	

3.6.1 Internal Supply Voltage Comparators

Every voltage regulator has an overvoltage comparator to detect a malfunction. If the nominal output voltage of 2.5 V is larger than V_{OVG} , V_{OVA} and V_{OVD} , then this overvoltage comparator is activated.

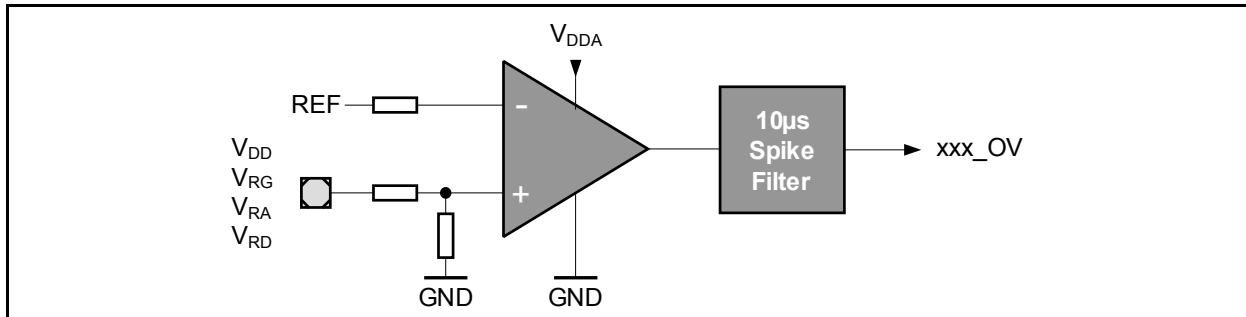


Figure 26 OV Comparator

3.6.2 V_{DD} Overvoltage Detection

The Overvoltage Detection Comparator monitors the external supply voltage at the V_{DD} pin. It activates the S_VR bit. (Figure 26)

3.6.3 GND - Off Comparator

The GND - Off Comparator is used to detect a voltage difference between the GND pin and SCK. It activates the S_VR bit of the SSC - Interface. This circuit can detect a disconnection of the Supply GND Pin.

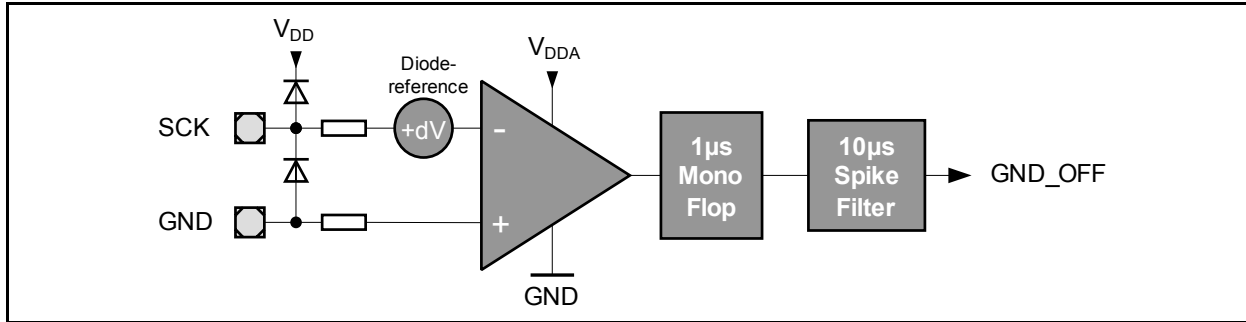


Figure 27 GND - Off Comparator

3.6.4 V_{DD} - Off Comparator

The V_{DD} - Off Comparator detects a disconnection of the VDD pin supply voltage. In this case, the TLE5012 is supplied by the SCK and CSQ input pins via the ESD structures. It activates the S_VR bit.

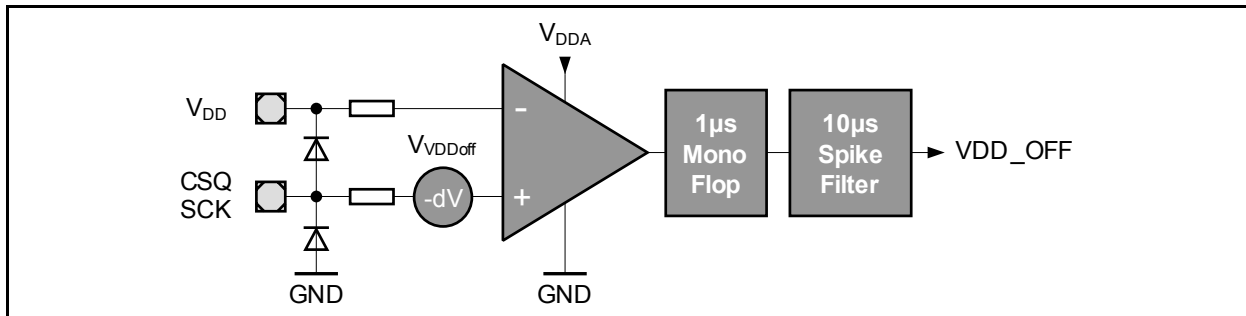


Figure 28 V_{DD} - Off Comparator

4 Package Information

4.1 Package Parameters

Table 20 Package Parameters

Parameter	Symbol	Limit Values			Unit	Notes
		min.	typ.	max.		
Thermal Resistance	R_{thJA}	-	150	200	K/W	Junction to Air ¹⁾
	R_{thJC}	-	-	75	K/W	Junction to Case
	R_{thJL}	-	-	85	K/W	Junction to Lead
Soldering Moisture Level		MSL 3				260°C
Lead Frame		Cu				
Plating		Sn 100%				> 7 µm

1) according to Jedec JESD51-7

4.2 Package Outline

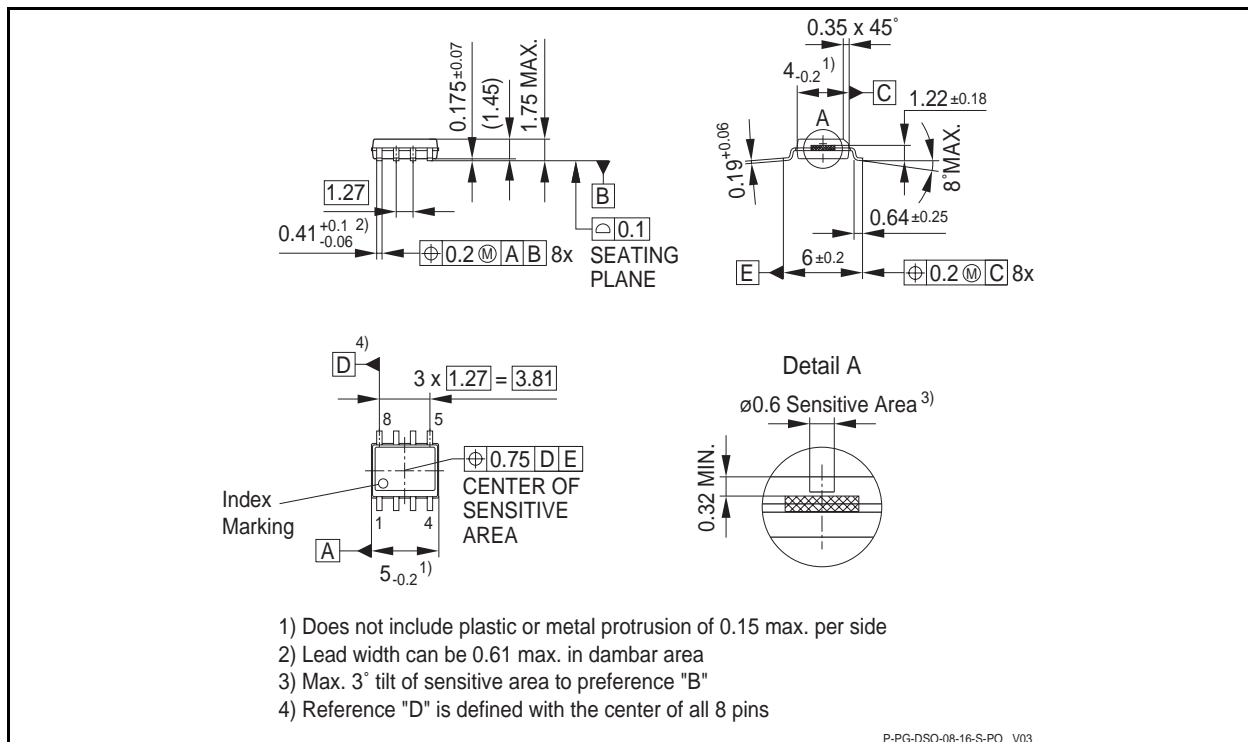


Figure 29 PG-DSO-8 Package Dimension

4.3 Footprint

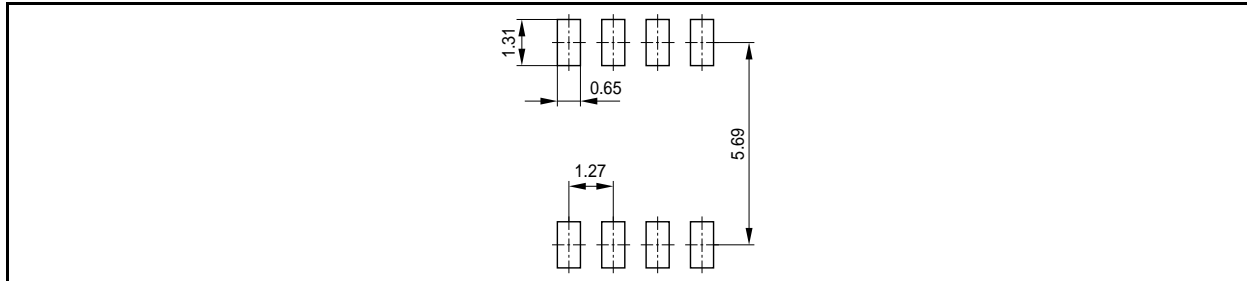


Figure 30 Footprint PG-DSO-8

4.4 Packing

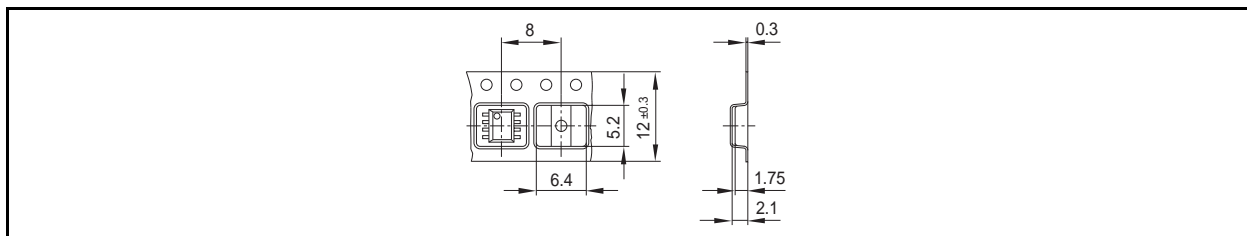


Figure 31 Tape and Reel

4.5 Marking

Position	Marking	Description
1st Line	5012xx	See ordering table on page 7
2nd Line	xxx	Lot code
3rd Line	Gxxxx	G..green, 4-digit..date code

Processing

Note: For processing recommendations, please refer to Infineon's Notes on processing

www.infineon.com

Published by Infineon Technologies AG